# Universal Quantum Transducers based on Surface Acoustic Waves

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We propose a universal, on-chip quantum transducer based on surface acoustic waves in piezoactive materials. Because of the intrinsic piezoelectric (and/or magnetostrictive) properties of the material, our approach provides a universal platform capable of coherently linking a broad array of qubits, including quantum dots, trapped ions, nitrogen-vacancy centers or superconducting qubits. The quantized modes of surface acoustic waves lie in the gigahertz range, can be strongly confined close to the surface in phononic cavities and guided in acoustic waveguides. We show that this type of surface acoustic excitations can be utilized efficiently as a quantum bus, serving as an on-chip, mechanical cavity-QED equivalent of microwave photons and enabling long-range coupling of a wide range of qubits.

#### I. INTRODUCTION

The realization of long-range interactions between remote qubits is arguably one of the greatest challenges towards developing a scalable, solid-state spin based quantum information processor [1]. One approach to address this problem is to interface qubits with a common quantum bus which distributes quantum information between distant qubits. The transduction of quantum information between stationary and moving qubits is central to this approach. A particularly efficient implementation of such a quantum bus can be found in the field of circuit QED where spatially separated superconducting qubits interact via microwave photons confined in transmission line cavities [2–4]. In this way, multiple qubits have been coupled successfully over relatively large distances of the order of millimeters [5, 6]. Fueled by the dramatic advances in the fabrication and manipulation of nanomechanical systems [7], an alternate line of research has pursued the idea of coherent, long-range interactions between individual qubits mediated by mechanical resonators, with resonant *phonons* playing the role of cavity photons [8– 13].

In this paper, we propose a new realization of a quantum transducer and data bus based on surface acoustic waves (SAW). SAWs involve phonon-like excitations bound to the surface of a solid and are widely used in modern electronic devices e.g. as compact microwave filters [14, 15]. Inspired by two recent experiments [16, 17], where the coherent quantum nature of surface acoustic waves (SAWs) has been explored, here we propose and analyze SAW phonon modes in piezo-active materials as a universal mediator for long-range couplings between remote qubits. Our approach involves qubits interacting with a localized SAW phonon mode, defined by a high-Q resonator, which in turn can be coupled weakly to a SAW waveguide serving as a quantum bus; as demonstrated below, the qubits can be encoded in a great variety of spin or charge degrees of freedom. We show that the Hamiltonian for an individual node (for a schematic representation see Fig.1) can take on the generic Jaynes-Cummings form ( $\hbar = 1$ ),

$$H_{\text{node}} = \frac{\omega_{\text{q}}}{2}\sigma^{z} + \omega_{c}a^{\dagger}a + g\left(\sigma^{+}a + \sigma^{-}a^{\dagger}\right), \qquad (1)$$

where  $\vec{\sigma}$  refers to the usual Pauli matrices describing the qubit with transition frequency  $\omega_{\rm q}$  and a is the bosonic operator for the localized SAW cavity mode of frequency  $\omega_c/2\pi \sim \text{GHz}$  [18]. The coupling g between the qubit and the acoustic cavity mode is mediated intrinsically by the

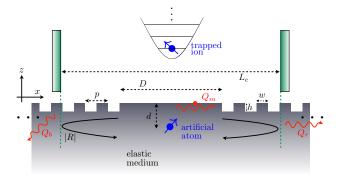


Figure 1: (color online). SAW as a universal quantum transducer. Distributed Bragg reflectors made of grooves form an acoustic cavity for surface acoustic waves. The resonant frequency of the cavity is determined by the pitch p,  $f_c = v_s/2p$ . Reflection occurs effectively at some distance inside the grating; the fictitious mirrors above the surface are not part of the actual experimental setup, but shown for illustrative purposes only. Red arrows indicate the relevant decay channels for the cavity mode: leakage through the mirrors, internal losses due to for example surface imperfections, and conversion into bulk modes. Qubits inside and outside of the solid can be coupled to the cavity mode. In more complex structures, the elastic medium can consist of multiple layers on top of some substrate.

piezo-properties of the host material, it is proportional to the electric or magnetic zero-point fluctuations associated with a single SAW phonon and, close to the surface, can reach values of  $g \sim 400$  MHz, much larger than the relevant decoherence processes and sufficiently large to allow for quantum effects and coherent coupling in the spin-cavity system as evidenced by cooperativities [19] of  $C \sim 10 - 100$  [see Section IV and Tab.I for definition and applicable values]. For  $\omega_{\rm q} \approx \omega_c$ ,  $H_{\rm node}$  allows for a controlled mapping of the qubit state onto a coherent phonon superposition, which can then be mapped to an itinerant SAW phonon in a waveguide, opening up the possibility to implement on-chip many quantum communication protocols well known in the context of optical quantum networks [13, 20].

The most pertinent features of our proposal can be summarized as follows: (1) Our scheme is not specific to any particular qubit realization, but-thanks to the plethora of physical properties associated with SAWs in piezo-active materials (strain, electric and magnetic fields)—provides a common on-chip platform accessible to various different implementations of qubits, comprising both natural (e.g., ions) and artificial candidates such as quantum dots or superconducting qubits. In particular, this opens up the possibility to interconnect dissimilar systems in new electro-acoustic quantum devices. (2) Typical SAW frequencies lie in the gigahertz range, closely matching transition frequencies of artificial atoms and enabling ground state cooling by conventional cryogenic techniques. (3) Our scheme is built upon an established technology [14, 15]: Lithographic fabrication techniques provide almost arbitrary geometries with high precision as evidenced by a large range of SAW devices such as delay lines, bandpass filters or resonators etc. In particular, the essential building blocks needed to interface qubits with SAW phonons have already been fabricated, according to design principles familiar from electromagnetic devices: (i) SAW resonators, the mechanical equivalents of Fabry-Perot cavities, with low-temperature measurements reaching quality factors of  $Q \sim 10^5$  even at gigahertz frequencies [21–23], and (ii) acoustic waveguides as analogue to optical fibers [14]. (4) For a given frequency in the gigahertz range, due to the slow speed of sound of approximately  $\sim 10^3 \text{m/s}$  for typical materials, device dimensions are in micrometer range, which is convenient for fabrication and integration with semiconductor components, and about  $10^5$  times smaller than corresponding electromagnetic resonators. (5) Since SAWs propagate elastically on the surface of a solid within a depth of approximately one wavelength, the mode volume is intrinsically confined in the direction normal to the surface. Further surface confinement then yields large zero-point fluctuations. (6) Yet another inherent advantage of our system is the intrinsic nature of the coupling. In piezoelectric materials, the SAW is accompanied by an electrical potential  $\phi$  which has the same spatial and temporal periodicities as the mechanical displacement and provides an intrinsic qubit-phonon coupling mechanism.

For example, recently qubit lifetimes in GaAs singlettriplet qubits were found to be limited by the piezoelectric electron-phonon coupling [24]. Here, our scheme provides a new paradigm, where coupling to phonons becomes a highly valuable asset for coherent quantum control rather than a liability.

In what follows, we first review the most important features of surface acoustic waves, with a focus on the associated zero-point fluctuations. Next, we discuss the different components making up the SAW-based quantum transducer and the acoustic quantum network it enables: SAW cavities, including a detailed analysis of the achievable quality factor Q, SAW waveguides and a variety of different candidate systems serving as qubits. Lastly, as exemplary application, we show how to transfer quantum states between distant nodes of the network under realistic conditions. Finally, we draw conclusions and give an outlook on future directions of research.

## **II. SAW PROPERTIES**

Elastic waves in piezoelectric solids are described by

$$\rho \ddot{u}_i - c_{ijkl} \partial_j \partial_l u_k = e_{kij} \partial_j \partial_k \phi, \qquad (2)$$

$$\epsilon_{ij}\partial_i\partial_j\phi = e_{ijk}\partial_i\partial_k u_j, \qquad (3)$$

where the vector  $\mathbf{u}(\mathbf{x}, t)$  denotes the displacement field (x is the cartesian coordinate vector),  $\rho$  is the mass density and repeated indices are summed over (i, j = x, y, z);  $c, \epsilon$  and e refer to the elasticity, permittivity and piezoelectric tensors, respectively [25]; they are largely defined by crystal symmetry [26]. For example, for cubic crystals such as GaAs there is only one non-zero component for the permittivity and the piezoelectric tensor, labeled as  $\epsilon$  and  $e_{14}$ , respectively [25]. Since elastic disturbances propagate much slower than the speed of light, it is common practice to apply the so-called quasi-static approximation [26] where the electric field is given by  $E_i = -\partial_i \phi$ . When considering surface waves, Eq.(2) and (3) must be supplemented by the mechanical boundary condition that there should be no forces on the free surface (taken to be at z = 0 with  $\hat{z}$  being the outward normal to the surface), that is  $T_{zx} = T_{zy} = T_{zz} = 0$  at z = 0 (where  $T_{ij} = c_{ijkl}\partial_l u_k + e_{kij}\partial_k \phi$  is the stress tensor), and appropriate electrical boundary conditions [25].

If not stated otherwise, the term SAW refers to the prototypical (piezoelectric) Rayleigh wave solution as theoretically and experimentally studied for example in Refs.[16, 17, 25, 27] and used extensively in different electronic devices [14, 15]. It is non-dispersive, decays exponentially into the medium with a characteristic penetration depth of a wavelength and has a phase velocity  $v_s = \omega/k$  that is lower than the bulk velocities in that medium, because the solid behaves less rigidly in the absence of material above the surface [26]. As a result, it cannot phase-match to any bulk-wave [14, 28]. As usual, we consider specific orientations for which the piezoelectric field produced by the SAW is strongest [14, 28], for

example a SAW with wavevector along the [110] direction of a (001) GaAs crystal [cf. Refs.[16, 25] and Appendices A and B].

SAWs in quantum regime.—In a semiclassical picture, an acoustic phonon associated with a SAW creates a time-dependent strain field,  $s_{kl} = (\partial_l u_k + \partial_k u_l)/2$  and a (quasi-static) electrical potential  $\phi(\mathbf{x}, t)$ . Upon quantization, the mechanical displacement becomes an operator that can be expressed in terms of the elementary normal modes as  $\hat{\mathbf{u}}(\mathbf{x}) = \sum_{n} [\mathbf{v}_{n}(\mathbf{x}) a_{n} + \text{h.c.}],$ where  $a_n(a_n^{\dagger})$  are bosonic annihilation (creation) operators for the vibrational eigenmode n and the set of normal modes  $\mathbf{v}_{n}(\mathbf{x})$  derives from the Helmholtzlike equation  $\mathcal{W}\mathbf{v}_n(\mathbf{x}) = -\rho\omega_n^2\mathbf{v}_n(\mathbf{x})$  associated with Eq.(2) and (3). The mode normalization is given by  $\int d^3 \mathbf{x} \rho \mathbf{v}_n^*(\mathbf{x}) \cdot \mathbf{v}_n(\mathbf{x}) = \hbar/2\omega_n$  [24, 29]. An important figure of merit in this context is the amplitude of the mechanical zero-point motion  $U_0$ . Along the lines of cavity QED [2], a simple estimate for  $U_0$  can be obtained by equating the *classical* energy of a SAW ~  $\int d^3 \mathbf{x} \rho \dot{\mathbf{u}}^2$  with the quantum energy of a single phonon, that is  $\hbar\omega$ . This leads directly to

$$U_0 \approx \sqrt{\hbar/2\rho v_s A},\tag{4}$$

where we used the dispersion relation  $\omega = v_s k$  and the intrinsic mode confinement  $V \approx A\lambda$  characteristic for SAWs. The quantity  $U_0$  refers to the mechanical amplitude associated with a single SAW phonon close to the surface. It depends only on the material parameters  $\rho$ and  $v_s$  and follows a generic  $\sim A^{-1/2}$  behaviour, where A is the effective mode area on the surface. The estimate given in Eq.(4) agrees very well with more detailed calculations presented in Appendix C. Several other important quantities which are central for signal transduction between qubits and SAWs follow directly from  $U_0$ : The (dimensionless) zero-point strain can be estimated as  $s_0 \approx$  $kU_0$ . The intrinsic piezoelectric potential associated with a single phonon derives from Eq.(3) as  $\phi_0 \approx (e_{14}/\epsilon) U_0$ [30]. Lastly, the electric field amplitude due to a single acoustic phonon is  $\xi_0 \approx k\phi_0 = (e_{14}/\epsilon) kU_0$ , illustrating the linear relation between electric field and strain characteristic for piezoelectric materials [8]. In summary, we typically find  $U_0 \approx 2 \text{fm} / \sqrt{A \, [\mu \text{m}^2]}$ , yielding  $U_0 \approx 2 \text{fm}$  for micron-scale confinement (cf. Appendix D). This is comparable to typical zero-point fluctuation amplitudes of localized mechanical oscillators [31]. Moreover, for micronscale surface confinement and GaAs material parameters, we obtain  $\xi_0 \approx 20 \text{V/m}$  which compares favorably with typical values of  $\sim 10^{-3}$ V/m and  $\sim 0.2$ V/m encountered in cavity and circuit QED, respectively [2].

For the sake of clarity, we have focused on piezoelectric materials so far. However, there are also piezomagnetic materials that exhibit a large magnetostrictive effect. In that case, elastic distortions are coupled to a (quasi-static) magnetic instead of electric field [32, 33]; for details see Appendix D. For typical materials such as Terfenol-D the magnetic field associated with a single phonon can be estimated as  $B_0 \approx (2-6)\mu T/\sqrt{A [\mu m^2]}$ .

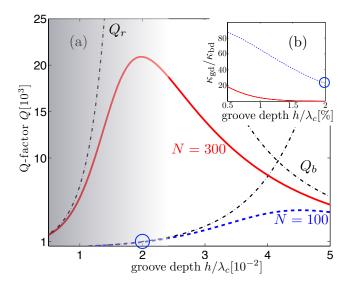


Figure 2: (color online). Characterization of a groove-based SAW cavity. (a) Quality factor Q for N = 100 (dashed blue) and N = 300 (red solid) grooves as a function of the normalized grove depth  $h/\lambda_c$ . For shallow grooves, Q is limited by leakage losses due to imperfect acoustic mirrors ( $Q_r$ -regime, gray area), whereas for deep grooves conversion to bulk modes dominates ( $Q_b$ -regime); compare asymptotics (dash-dotted lines). (b) Ratio of desired to undesired decay rates  $\kappa_{\rm gd}/\kappa_{\rm bd}$ . The stronger Q is dominated by  $Q_r$ , the higher  $\kappa_{\rm gd}/\kappa_{\rm bd}$ . Here, w/p = 0.5,  $D = 5.25\lambda_c$ , and  $f_c = 3$ GHz; typical material parameters for LiNbO<sub>3</sub> have been used [cf. Appendix E].

Finally, we note that composite structures comprising both piezoelectric and piezomagnetic materials can support magneto-electric surface acoustic waves [34, 35].

## **III. SAW CAVITIES & WAVEGUIDES**

SAW cavities.—To boost single phonon effects, it is essential to increase  $U_0$ . In analogy to cavity QED, this can be achieved by confining the SAW mode in an acoustic resonator. The physics of SAW cavities has been theoretically studied and experimentally verified since the early 1970s [14, 36]. Here, we provide an analysis of a SAW cavity based on an on-chip distributed Bragg reflector in view of potential applications in quantum information science; for details see Appendix E. SAW resonators of this type can usually be designed to host a single resonance  $f_c = \omega_c/2\pi = v_s/\lambda_c$  ( $\lambda_c = 2p$ ) only and can be viewed as an acoustic Fabry-Perot resonator with effective reflection centers, sketched by localized mirrors in Fig.1, situated at some effective penetration distance into the grating [14]. Therefore, the total effective cavity size along the mirror axis is  $L_c > D$ , where D is the physical gap between the gratings. The total cavity line-width  $\kappa$  =  $\omega_c/Q$  =  $\kappa_{\rm gd}+\kappa_{\rm bd}$  can be decomposed into desired (leakage through the mirrors) and undesired (conversion into bulk modes and internal losses due to surface imperfections etc.) losses, labeled as  $\kappa_{\rm gd}$  and

 $\kappa_{\rm bd}$ , respectively; for a schematic illustration compare Fig.1. For the total quality factor Q, we can typically identify three distinct regimes [cf. Fig.2]: For very small groove depths  $h/\lambda_c \leq 2\%$ , losses are dominated by coupling to SAW modes outside of the cavity, dubbed as  $Q_r$ -regime ( $\kappa_{\rm gd} \gg \kappa_{\rm bd}$ ), whereas for very deep grooves losses due to conversion into bulk-modes become excessive  $(Q_b$ -regime,  $\kappa_{\rm gd} \ll \kappa_{\rm bd})$ . In between, for a sufficiently high number of grooves N, the quality factor Q can ultimately be limited by internal losses (surface cracks etc.), referred to as  $Q_m$ -regime ( $\kappa_{\rm gd} \ll \kappa_{\rm bd}$ ). For  $N\approx$  300, we find that the onset of the bulk-wave limit occurs for  $h/\lambda_c \gtrsim 2.5\%$ , in excellent agreement with experimental findings [36, 37]. With regard to applications in quantum information schemes, the  $Q_r$ -regime plays a special role in that resonator phonons leaking out through the acoustic mirrors can be processed further by guiding them in acoustic SAW waveguides (see below). To capture this behaviour quantitatively, we analyze  $\kappa_{\rm gd}/\kappa_{\rm bd}$  [cf. Fig.2]: for  $\kappa_{\rm gd}/\kappa_{\rm bd} \gg 1$ , leakage through the mirrors is the strongest decay mechanism for the cavity phonon, whereas the undesired decay channels are suppressed. Our analysis shows that, for gigahertz frequencies  $f_c \approx 3 \text{GHz}$ ,  $N \approx 100$  and  $h/\lambda_c \approx 2\%$ , a quality factor of  $Q \approx 10^3$  is achievable, together with an effective cavity confinement  $L_c \approx 40\lambda_c$  (for  $D \leq 5\lambda_c$ ) and  $\kappa_{\rm gd}/\kappa_{\rm bd} \gtrsim 20$  (illustrated by the circle in Fig.2); accordingly, the probability for a cavity phonon to leak through the mirrors (rather than into the bulk for example) is  $\kappa_{\rm gd}/(\kappa_{\rm gd}+\kappa_{\rm bd}) \gtrsim 95\%$ . Note that the resulting total cavity linewidth of  $\kappa/2\pi = f_c/Q \approx (1-3)$  MHz is similar to the ones typically encountered in circuit QED [6]. To compare this to the effective cavity-qubit coupling, we need to fix the effective mode area of the SAW cavity. In addition to the longitudinal confinement by the Bragg mirror (as discussed above) a transverse confinement length  $L_{\text{trans}}$  (in direction  $\hat{y}$ ) can be provided, e.g., using waveguiding, etching or (similar to cavity QED) focusing techniques [14, 38, 39]. For transverse confinement  $L_{\rm trans} \approx (1-5) \, \mu {\rm m}$  and a typical resonant cavity wavelength  $\lambda_c \approx 1 \mu m$ , the effective mode area is then  $A = L_{\rm trans} L_c \approx (40 - 200) \mu {\rm m}^2$ . In the desired regime  $\kappa_{\rm gd}/\kappa_{\rm bd} \gg 1$ , this is largely limited by the deliberately low reflectivity of a single groove; accordingly, the cavity mode leaks strongly into the grating such that  $L_c \gg D$ [cf. Appendix  $\mathbf{E}$  for details]. While we have focused on this standard Bragg design (due to its experimentally validated frequency selectivity and quality factors), let us shortly mention potential approaches to reduce A and thus increase single-phonon effects even further: (i) The most straightforward strategy (that is still compatible with the Bragg mirror design) is to reduce  $\lambda_c$  as much as possible, down to the maximum frequency  $f_c = v_s/\lambda_c$ that can still be made resonant with the (typically highly tunable) qubit's transition frequency  $\omega_{\rm q}/2\pi$ ; note that fundamental Rayleigh modes with  $f_c \approx 6 \text{GHz}$  have been demonstrated experimentally [40]. (ii) In order to increase the reflectivity of a single groove, one could use deeper grooves. To circumvent the resulting increased losses into the bulk [cf. Fig.2(b)], free-standing structures (where the effect of bulk phonon modes is reduced) could be employed. (iii) Lastly, alternative cavity designs such as so-called trapped energy resonators make it possible to strongly confine acoustic resonances in the center of plate resonators [41].

SAW waveguides.—Not only can SAWs be confined in cavities, but they can also be guided in acoustic waveguides (WGs) [14, 42]. Two dominant types of design are: (i) Topographic WGs such as ridge-type WGs where the substrate is locally deformed using etching techniques, or (ii) overlay WGs (such as strip- or slot-type WGs) where one or two strips of one material are deposited on the substrate of another to form core and clad regions with different acoustic velocities. If the SAW velocity is slower (higher) in the film than in the substrate, the film acts as a core (cladding) for the guide whereas the unmodified substrate corresponds to the cladding (core). An attenuation coefficient of  $\sim 0.6 dB/mm$  has been reported for a  $10\mu$ m-wide slot-type WG, defined by Al cladding layers on a GaAs substrate [38, 39]. This shows that SAWs can propagate basically dissipation-free over chip-scale distances exceeding several millimeters. Typically, onedimensional WG designs have been investigated, butto expand the design flexibility—one could use multiple acoustic lenses in order guide SAWs around a bend [28].

### IV. UNIVERSAL COUPLING

Versatility.—To complete the analogy with cavity QED, a non-linear element similar to an atom needs to be introduced. In the following, we highlight three different exemplary systems, illustrating the versatility of our SAW-based platform. We focus on quantum dots, trapped ions and NV-centers, but similar considerations naturally apply to other promising quantum information candidates such as superconducting qubits [7, 8, 17, 43], Rydberg atoms [44] or electron spins bound to a phosphorus donor atom in silicon [40]. In all cases considered, a single cavity mode a, with frequency  $\omega_c$  close to the relevant transition frequency, is retained. We provide estimates for the single-phonon coupling strength and cooperativity [cf. Tab.I], while more detailed analyses go beyond the scope of this work and are subject to future research.

(i) QD Charge qubit: A natural candidate for our scheme is a charge qubit embedded in a lithographically defined GaAs double quantum dot (DQD) containing a single electron. The DQD can well be described by an effective two-level system, characterized by an energy offset  $\epsilon$  and interdot tunneling  $t_c$  yielding a level splitting  $\Omega = \sqrt{\epsilon^2 + 4t_c^2}$  [45]. The electron's charge e couples to the piezoelectric potential; the deformation coupling is much smaller than the piezoelectric coupling and can therefore safely be neglected [46]. Since the quantum dot is small compared to the SAW wavelength, we ne-

charge qubit (DQD) spin qubit (DQD) trapped ion NV-center

			11	
coupling $g$	(200 - 450)MHz	(10 - 22.4)MHz	(1.8 - 4.0)kHz	(45-101)kHz
cooperativity ${\cal C}$	11 - 55	21 - 106	7 - 36	10 - 54

Table I: Estimates for single-phonon coupling strength g and cooperativity C. We have used  $A = (1-5)\mu m \times 40\lambda_c$ , T = 20mK [17], (conservative) quality factors of  $Q = (1, 1, 3, 1) \times 10^3$  and frequencies of  $\omega_c = 2\pi (6, 1.5, 2 \times 10^{-3}, 3)$  GHz for the four systems listed. For the spin qubit  $T_2^* = 2\mu s$  [68], and for the trapped ion scenario,  $g_{ion}(C_{ion})$  is given for  $d = 150\mu m$  due to the prolonged dephasing time further away from the surface ( $C_{ion}$  improves with increasing d, even though  $g_{ion}$  decreases, up to a point where other dephasing start to dominate). Further details can be found in the main text.

glect potential effects coming from the structure making up the dots (heterostructure and metallic gates); for a detailed discussion see Appendix I. Performing a standard rotating-wave approximation (valid for  $\delta, g_{ch} \ll \omega_c$ ), we find that the system can be described by a Hamiltonian of Jaynes-Cummings form,

$$H_{\rm dot} = \delta S^z + g_{\rm ch} \frac{2t_c}{\Omega} \left( S^+ a + S^- a^\dagger \right), \qquad (5)$$

where  $\delta = \Omega - \omega_{\rm c}$  specifies the detuning between the qubit and the cavity mode, and  $S^{\pm} = |\pm\rangle \langle \mp |$  (and so on) refer to pseudo-spin operators associated with the eigenstates  $|\pm\rangle$  of the DQD Hamiltonian (cf. Appendix F). The Hamiltonian  $H_{\rm dot}$  describes the coherent exchange of excitations between the qubit and the acoustic cavity mode. The strength of this interaction  $g_{\rm ch} = e\phi_0 \mathcal{F}(kd) \sin(kl/2)$  is proportional to the charge e and the piezoelectric potential associated with a single phonon  $\phi_0$ . The decay of the SAW mode into the bulk is captured by the function  $\mathcal{F}(kd)$  [d is the distance between the DQD and the surface; see Appendix B for details], while the factor  $\sin(kl/2)$  reflects the assumed mode function along the axis connecting the two dots, separated by a distance l. For (typical) values of  $l \approx \lambda_c/2 = 250$ nm and  $d \approx 50$ nm  $\ll \lambda_c$ , the geometrical factor  $\mathcal{F}(kd)\sin(kl/2)$  then leads to a reduction in coupling strength compared to the bare value  $e\phi_0$  (at the surface) by a factor of ~ 2 only. In total, we then obtain  $g_{\rm ch} \approx 2 {\rm GHz} / \sqrt{A \, [\mu {\rm m}^2]}$ . For lateral confinement  $L_{\text{trans}} \approx (1-5) \,\mu\text{m}$ , the effective mode area is  $A = L_{\rm trans} L_c \approx (20 - 100) \mu {\rm m}^2$ . The resulting chargeresonator coupling strength  $g_{\rm ch} \approx (200 - 450) {\rm MHz}$  compares well with values obtained using superconducting qubits coupled to *localized* nano-mechanical resonators made of piezoelectric material where  $q \approx (0.4 - 1.2)$ GHz [7, 8] or superconducting resonators coupled to Cooper pair box qubits  $(g/2\pi \approx 6 \text{MHz})$  [3], transmon qubits  $(q/2\pi \approx 100 \text{MHz})$  [47] and indium arsenide DQD qubits  $(g/2\pi \approx 30 \text{MHz})$  [48]. Note that, in principle, the coupling strength  $g_{ch}$  could be further enhanced by additionally depositing a strongly piezoelectric material such as  $LiNbO_3$  on the GaAs substrate [16]. Moreover, with a LiNbO<sub>3</sub> film on top of the surface, also non-piezoelectric materials such as Si or Ge could be used to host the quantum dots [49]. The level splitting  $\Omega(t)$  and interdot tunneling  $t_{c}(t)$  can be tuned in-situ via external gate voltages. By controlling  $\delta$  one can rapidly turn on and off the interaction between the qubit and the cavity: For

an effective interaction time  $\tau = \pi/2g_{\text{eff}} (g_{\text{eff}} = 2g_{\text{ch}}t_c/\Omega)$ on resonance  $(\delta = 0)$ , an arbitrary state of the qubit is swapped to the absence or presence of a cavity phonon, i.e.,  $(\alpha | -\rangle + \beta | +\rangle) |0\rangle \rightarrow |-\rangle (\alpha |0\rangle - i\beta |1\rangle)$ , where  $|n\rangle$ labels the Fock states of the cavity mode. Apart from this SWAP operation, further quantum control techniques known from cavity QED may be accessible [50]. Note that below we will generalize our results to *spin* qubits embedded in DQDs.

(ii) Trapped ion: The electric field associated with the SAW mode does not only extend into the solid, but, for a free surface, in general there will also be an electrical potential decaying exponentially into the vacuum above the surface  $\sim \exp[-k|z|]$  [25]; cf. Appendix B. This allows for coupling to systems situated above the surface, without any mechanical contact. For example, consider a single ion of charge q and mass m trapped at a distance d above the surface of a strongly piezoelectric material such as LiNbO<sub>3</sub> or AlN. The electric dipole induced by the ion motion couples to the electric field of the SAW phonon mode. The dynamics of this system are described by the Hamiltonian

$$H_{\rm ion} = \omega_{\rm c} a^{\dagger} a + \omega_t b^{\dagger} b + g_{\rm ion} \left( a b^{\dagger} + a^{\dagger} b \right), \qquad (6)$$

where b refers to the annihilation operator of the ion's motional mode and  $\omega_t$  is the (axial) trapping frequency. The single phonon coupling strength is given by  $g_{ion} =$  $qx_0 \times k_c \phi_0 F(k_c d) = q \phi_0 F(k_c d) \eta_{\text{LD}}$ . Apart from the exponential decay  $F(kd) = \exp[-kd]$ , the effective coupling is reduced by the Lamb-Dicke parameter  $\eta_{\rm LD}$  =  $2\pi x_0/\lambda_c$ , with  $x_0 = \sqrt{\hbar/2m\omega_t}$ , since the motion of the ion is restricted to a region small compared with the SAW wavelength  $\lambda_c$ . For LiNbO<sub>3</sub>, a surface mode area of  $A = (1-5)\mu m \times 40\lambda_c$ , the commonly used <sup>9</sup>Be<sup>+</sup> ion and typical ion trap parameters with  $d \approx 30 \mu \text{m}$  and  $\omega_t/2\pi \approx 2$ MHz [51], we obtain  $g_{\rm ion} \approx (3-6.7)$ kHz. Here,  $g_{\rm ion}$  refers to the coupling between the ion's motion and the cavity. However, based on  $H_{\rm ion}$ , one can in principle generalize the well-known protocols operating on the ion's spin and motion to operations on the spin and the acoustic phonon mode [52].

(iii) NV-center: Yet another system well suited for our scheme are NV centers in diamond. Even though diamond itself is not piezoactive, it has played a key role in the context of high-frequency SAW devices due to its record-high sound velocity [14]; for example, highperformance SAW resonators with a quality factor of

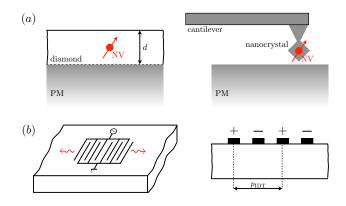


Figure 3: (color online). (a) Schematic illustration for coupling to a NV center via a piezo-magnetic (PM) material (see text for details); surface grooves (not shown) can be used to provide SAW phonon confinement. (b) SAWs can be generated electrically based on standard interdigital transducers (IDTs) deposited on the surface. Typically, an IDT consists of two thin-film electrodes on a piezo-electric material, each formed by interdigitated fingers. When an ac voltage is applied to the IDT on resonance (defined by the periodicity of the fingers as  $\omega_{\rm IDT}/2\pi = v_s/p_{\rm IDT}$ , where  $v_s$  is the SAW propagation speed), it launches a SAW across the substrate surface in the two directions perpendicular to IDT fingers[14, 15, 17].

Q = 12500 at  $\omega_c\gtrsim$  10GHz were experimentally demonstrated for AlN/diamond heterostructures [53, 54]. To make use of the large magnetic coupling coefficient of the NV center spin  $\gamma_{\rm NV} = 2\pi \times 28 {\rm GHz/T}$ , here we consider a hybrid device composed of a thin layer of diamond with a single (negatively charged) NV center with groundstate spin **S** implanted a distance  $d \approx 10$  nm away from the interface with a strongly piezo-magnetic material. Equivalently, building upon current quantum sensing approaches [55, 56], one could use a diamond nanocrystal (typically  $\sim 10$  nm in size) in order to get the NV centre extremely close to the surface of the piezo-magnetic material and thus maximize the coupling to the SAW cavity mode; compare Fig.3(a) for a schematic illustration. In the presence of an external magnetic field  $\mathbf{B}_{\text{ext}}$  [57], the system is described by

$$H_{\rm NV} = DS_z^2 + \gamma_{\rm NV} \mathbf{B}_{\rm ext} \cdot \mathbf{S} + \omega_{\rm c} a^{\dagger} a \qquad (7)$$
$$+ g_{\rm NV} \sum_{\alpha = x, y, z} \eta_{\rm NV}^{\alpha} S^{\alpha} \left( a + a^{\dagger} \right),$$

where  $D = 2\pi \times 2.88$ GHz is the zero-field splitting,  $g_{\rm NV} = \gamma_{\rm NV}B_0$  is the single phonon coupling strength and  $\eta_{\rm NV}^{\alpha}$  is a dimensionless factor encoding the orientation of the NV spin with respect to the magnetic stray field of the cavity mode. For  $d \ll \lambda_c$ , a rough estimate shows that at least one component of  $\eta_{\rm NV}^{\alpha}$  is of order unity [33]. For a NV center close to a Terfenol-D layer of thickness  $h \gg \lambda_c$ , we find  $g_{\rm NV} \approx 400$ kHz/ $\sqrt{A \ [\mu m^2]}$ . Thus, as compared to direct strain coupling  $\leq 200$ Hz/ $\sqrt{A \ [\mu m^2]}$ , the presence of the piezomagnetic layer is found to boost the single phonon coupling strength by three orders of magnitude; this is in agreement with previous theoretical results for a static setting [33].

Decoherence.—In the analysis above, we have ignored the presence of decoherence which in any realistic setting will degrade the effects of coherent qubit-phonon interactions. In this context, the cooperativity parameter, defined as  $C = g^2 T_2 / [\kappa (\bar{n}_{\rm th} + 1)]$ , is a key figure of merit. Here,  $T_2$  refers to the corresponding dephasing time, while  $\bar{n}_{\rm th} = (\exp [\hbar \omega_c / k_B T] - 1)^{-1}$  gives the thermal occupation number of the cavity mode at temperature T. The parameter C compares the coherent singlephonon coupling strength g with the geometric mean of the qubit's decoherence rate  $\sim T_2^{-1}$  and the cavity's effective linewidth  $\sim \kappa (\bar{n}_{\rm th} + 1)$ ; in direct analogy to cavity QED, C > 1 marks the onset of coherent quantum effects in a coupled spin-oscillator system, even in the presence of noise; cf. Ref.[10] and Appendix H for a detailed discussion. To estimate C, we take the following parameters for the dephasing time  $T_2$ : For system (i)  $T_2\approx 10 \mathrm{ns}$  has been measured close to the charge degeneracy point  $\epsilon = 0$  [45]. In scenario (ii) motional decoherence rates of 0.5Hz have been measured in a cryogenically cooled trap for an ion height of  $150\mu m$  and 1MHz motional frequency [51]. Since this rate scales as  $\sim d^{-4}$ [52, 58], we take  $T_2$  [s]  $\approx 2(d \,[\mu m] / 150)^4$ . Lastly, for the NV-center (iii)  $T_2 \approx 0.6$ s has been demonstrated for ensembles of NV spins [59] and we assume an optimistic value of  $T_2 = 100$  ms, similarly to Ref.[60]. The results are summarized in Tab.I. We find that C > 1 should be experimentally feasible which is sufficient to perform a quantum gate between two spins mediated by a *thermal* mechanical mode [9].

Qubit-qubit coupling.—When placing a pair of qubits into the *same* cavity, the regime of large single spin cooperativity  $C \gg 1$  allows for coherent cavity-phononmediated interactions and quantum gates between the two spins via the effective interaction Hamiltonian  $H_{\rm int} =$  $g_{\rm dr}(S_1^+S_2^- + {\rm h.c.})$ , where  $g_{\rm dr} = g^2/\delta \ll g$  in the so-called dispersive regime [4]. For the estimates given in Tab.I, we have restricted ourselves to the  $Q_r$ -regime with  $Q \approx 10^3$ , where leakage through the acoustic mirrors dominates over undesired (non-scalable) phonon losses ( $\kappa_{\rm gd} \gg \kappa_{\rm bd}$ ). However, note that small-scale experiments using a single cavity only (where there is no need for guiding the SAW phonon into a waveguide for further quantum information processing) can be operated in the  $Q_m$ -regime (which is limited only by internal material losses), where the quality factor  $Q \approx Q_m \gtrsim 10^5$  is maximized (and thus overall phonon losses minimal).

As a specific example, consider two NV-centers, both coupled with strength  $g_{\rm NV} \approx 100 {\rm kHz}$  to the cavity and in resonance with each other, but detuned from the resonator. Since for large detuning  $\delta$  the cavity is only virtually populated, the cavity decay rate is reduced to  $\kappa_{\rm dr} = (g^2/\delta^2) \kappa \approx 10^{-2} \kappa \approx 1 {\rm kHz}$  (for  $f_c = 3 {\rm GHz}, Q = 2 \times 10^5$ ), whereas the spin-spin coupling is  $g_{\rm dr} \approx 0.1 g_{\rm NV} \approx 10 {\rm kHz}$ . Therefore,  $T_2 = 1 {\rm ms}$  is already sufficient to approach the strong-coupling regime where  $g_{\rm dr} \gg \kappa_{\rm dr}, T_2^{-1}$ .

Finally, we note that, in all cases considered above, one could implement a coherent, electrical control by pumping the cavity mode using standard interdigital transducers (IDTs) [14, 15, 17]; compare Fig.3(b) for a schematic illustration. The effect of the additional Hamiltonian  $H_{\rm drive} = \Xi \cos(\omega_{\rm IDT}t) [a + a^{\dagger}]$  can be accounted for by replacing the cavity state by a coherent state, that is  $a \to \alpha$ . For example, in the case of Eq.(5), one could then drive Rabi oscillations between the states  $|+\rangle$  and  $|-\rangle$  with the amplified Rabi frequency  $\Omega_R = g\alpha$ .

## V. STATE TRANSFER PROTOCOL

The possibility of quantum transduction between SAWs and different realizations of stationary qubits enables a variety of applications including quantum information achitectures that use SAW phonons as a quantum bus to couple dissimilar and/or spatially separated qubits. The most fundamental task in such a quantum network is the implementation of a state transfer protocol between two remote qubits 1 and 2, which achieves the mapping  $(\alpha | 0 \rangle_1 + \beta | 1 \rangle_1) \otimes | 0 \rangle_2 \rightarrow | 0 \rangle_1 \otimes (\alpha | 0 \rangle_2 + \beta | 1 \rangle_2)$ . In analogy to optical networks, this can be accomplished via coherent emission and reabsorption of a single phonon in a waveguide [13]. As first shown in the context of atomic QED [20], in principle perfect, deterministic state transfer can be implemented by identifying appropriate time-dependent control pulses.

Before we discuss a specific implementation of such a transfer scheme in detail, we provide a general approximate result for the state transfer fidelity  $\mathcal{F}$ . As demonstrated in detail in Appendix H, for small infidelities one can take

$$\mathcal{F} \approx 1 - \varepsilon - \mathcal{C}C^{-1},\tag{8}$$

as a *general* estimate for the state transfer fidelity. Here, individual errors arise from intrinsic phonon losses  $\sim$  $\varepsilon = \kappa_{\rm bd}/\kappa_{\rm gd}$  and qubit dephasing  $\sim C^{-1} \sim T_2^{-1}$ , respectively; the numerical coefficient  $\mathcal{C} \sim \mathcal{O}(1)$  depends on the specific control pulse and may be optimized for a given set of experimental parameters [61]. This simple, analytical result holds for a Markovian noise model where qubit dephasing is described by a standard pure dephasing term leading to an exponential loss of coherence  $\sim \exp\left(-t/T_2\right)$  and agrees well with numerical results presented in Ref.[61]. For non-Markovian qubit dephasing an even better scaling with C can be expected [9]. Using experimentally achievable parameters  $\varepsilon \approx 5\%$ and  $C \approx 30$ , we can then estimate  $\mathcal{F} \approx 90\%$ , showing that fidelities sufficiently high for quantum communication should be feasible for all physical implementations listed in Tab.I.

In the following, we detail the implementation of a transfer scheme based on *spin* qubits implemented in gate-defined double quantum dots (DQDs) [62]. In particular, we consider singlet-triplet-like qubits encoded in

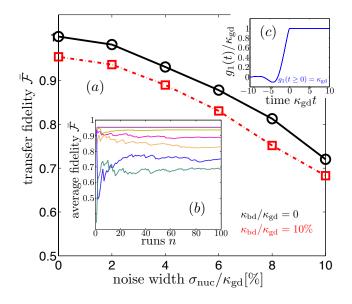


Figure 4: (color online). (a) Average fidelity  $\bar{\mathcal{F}}$  of the state transfer protocol for a coherent superposition  $|\psi\rangle = (|0\rangle - |1\rangle)/\sqrt{2}$  in the presence of quasi-static (non-Markovian) Overhauser noise, as a function of the rootmean-square fluctuations  $\sigma_{\text{nuc}}$  in the detuning parameters  $\delta_i (i = 1, 2)$ , for  $\kappa_{\text{bd}}/\kappa_{\text{gd}} = 0$  (solid line, circles) and  $\kappa_{\text{bd}}/\kappa_{\text{gd}} = 10\%$  (dash-dotted line, squares). (b) After n = 100runs with random values for  $\delta_i$ ,  $\bar{\mathcal{F}}$  approximately reaches convergence. The curves refer to  $\sigma_{\text{nuc}}/\kappa_{\text{gd}} = (0, 2, \dots, 10)\%$ (from top to bottom) for  $\kappa_{\text{bd}}/\kappa_{\text{gd}} = 10\%$ . (c) Pulse shape  $g_1(t)$  for first node.

lateral QDs, where two electrons are localized in adjacent, tunnel-coupled dots. As compared to the charge qubits discussed above, this system is known to feature superior coherence timescales [63–66]; these are largely limited by the relatively strong hyperfine interaction between the electronic spin and the nuclei in the host environment [64], resulting in a random, slowly evolving magnetic (Overhauser) field for the electronic spin. To mitigate this decoherence mechanism, two common approaches are (i) spin-echo techniques which allow to extend spin-coherence from a time-ensemble-averaged dephasing time  $T_2^{\star} \approx 100$ ns to  $T_2 \gtrsim 250 \mu s$  [66], and (ii) narrowing of the nuclear field distribution [64, 67]. Recently, real-time adaptive control and estimation methods (that are compatible with arbitrary qubit operations) have allowed to narrow the nuclear spin distribution to values that prolong  $T_2^{\star}$  to  $T_2^{\star} > 2\mu s$  [68]. For our purposes, the latter is particularly attractive as it can be done simply before loading and transmitting the quantum information, whereas spin-echo techniques can be employed as well, however at the expense of more complex pulse sequences (see Appendix for details). In order to couple the electric field associated with the SAW cavity mode to the electron *spin* states of such a DQD, the essential idea is to make use of an effective electric dipole moment associated with the exchange-coupled spin states of the DQD [69–72]. As detailed in Appendix G, we then find that in the usual singlet-triplet subspace spanned by the two-electron states  $\{|\uparrow\downarrow\rangle\rangle, |\downarrow\uparrow\uparrow\rangle\}$ , a single node can well be described by the prototypical Jaynes-Cummings Hamiltonian given in Eq.(1). As compared to the direct charge coupling  $g_{ch}$ , the single phonon coupling strength g is reduced since the qubit states  $|l\rangle$ have a small admixture of the localized singlet  $\langle S_{02}|l\rangle$ (l = 0, 1) only. Using typical parameters values, we find  $g \approx 0.1g_{ch} \approx 200 \text{MHz}/\sqrt{A [\mu m^2]}$  [73]. In this system, the coupling g(t) can be tuned with great flexibility via both the tunnel-coupling  $t_c$  and/or the detuning parameter  $\epsilon$ .

The state transfer between two such singlet-triplet qubits connected by a SAW waveguide can be adequately described within the theoretical framework of cascaded quantum systems, as outlined in detail for example in Refs.[13, 20, 74, 75]: The underlying quantum Langevin equations describing the system can be converted into an effective, cascaded Master equation for the system's density matrix  $\rho$ . For the relevant case of two qubits, it can be written as  $\dot{\rho} = \mathcal{L}_{\text{ideal}}\rho + \mathcal{L}_{\text{noise}}\rho$ , where

$$\mathcal{L}_{\text{ideal}}\rho = -i \left[ H_S(t) + i\kappa_{\text{gd}} \left( a_1^{\dagger}a_2 - a_2^{\dagger}a_1 \right), \rho \right] + 2\kappa_{\text{gd}}\mathcal{D} \left[ a_1 + a_2 \right] \rho, \qquad (9)$$

$$\mathcal{L}_{\text{noise}}\rho = 2\kappa_{\text{bd}} \sum_{i=1,2} \mathcal{D}\left[a_i\right]\rho - i \sum_i \delta_i \left[S_i^z, \rho\right].$$
(10)

Here,  $\mathcal{D}[a] \rho = a\rho a^{\dagger} - \frac{1}{2} \{a^{\dagger}a, \rho\}$  is a Lindblad term with jump operator a and  $H_S(t) = \sum_i H_i(t)$ , with  $H_i(t) = g_i(t) [S_i^+ a_i + S_i^- a_i^{\dagger}]$  describes the coherent Jaynes-Cummings dynamics of the two nodes. The ideal cascaded interaction is captured by  $\mathcal{L}_{ideal}$  which contains the non-local coherent environment-mediated coupling transferring excitations from qubit 1 to qubit 2 [76], while  $\mathcal{L}_{\text{noise}}$  summarizes undesired decoherence processes: We account for intrinsic phonon losses (bulk-mode conversion etc.) with a rate  $\kappa_{bd}$  and (non-exponential) qubit dephasing. Since the nuclear spins evolve on relatively long time-scales, the electronic spins in quantum dots typically experience non-Markovian noise leading to a nonexponential loss of coherence on a characteristic timescale  $T_2^{\star}$  given by the width of the nuclear field distribution  $\sigma_{\rm nuc}$  as  $T_2^{\star} = \sqrt{2}/\sigma_{\rm nuc}$  [64, 68]. Recently, a record-low value of  $\sigma_{\rm nuc}/2\pi = 80$ kHz has been reported [68], yielding an extended time-ensemble-averaged electron dephasing time of  $T_2^{\star} = 2.8 \mu s$ . In our model, to realistically account for the dephasing induced by the quasi-static, yet unknown Overhauser field, the detuning parameters  $\delta_i$  are sampled independently from a normal distribution  $p(\delta_i)$  with zero mean (since nominal resonance can be achieved via the electronic control parameters) and standard deviation  $\sigma_{\rm nuc}$  [67]; see Appendix G for details. In Appendix J we also provide numerical results for standard Markovian dephasing, showing that non-Markovian noise is beneficial in terms of faithful state transfer.

Under ideal conditions where  $\mathcal{L}_{\text{noise}} = 0$ , the setup is analogous to the one studied in Ref.[20] and the same time-symmetry arguments can be employed to determine the optimal control pulses  $g_i(t)$  for faithful state transfer: if a phonon is emitted by the first node, then, upon reversing the direction of time, one would observe perfect reabsorption. By engineering the emitted phonon wavepacket such that it is invariant under time reversal and using a time-reversed control pulse for the second node  $g_2(t) = g_1(-t)$ , the absorption process in the second node is a time-reversed copy of the emission in the first and therefore in principle perfect. Based on this reasoning (for details see Ref.[20]), we find the explicit, optimal control pulse shown in Fig.4(c).

To account for noise, we simulate the full master equation numerically. The results are displayed in Fig.4(a), where for every random pair  $\delta = (\delta_1, \delta_2)$  the fidelity of the protocol is defined as the overlap between the target state  $|\psi_{\text{tar}}\rangle$  and the actual state after the transfer  $\rho(t_f)$ , that is  $\mathcal{F}_{\delta} = \langle \psi_{\text{tar}} | \rho(t_f) | \psi_{\text{tar}} \rangle$ . The average fidelity  $\overline{\mathcal{F}}$  of the protocol is determined by averaging over the classical noise in  $\delta$ , that is  $\overline{\mathcal{F}} = \int d\delta_1 d\delta_2 p(\delta_1) p(\delta_2) \mathcal{F}_{\delta}$ . Taking an effective mode area  $A \approx 100 \mu \text{m}^2$  as above and  $Q \approx 10^3$ to be well within the  $Q_r$ -regime where  $\kappa_{\rm bd}/\kappa_{\rm gd} \approx 5\%$ , we have  $g \approx \kappa_{\rm gd} \approx 20$  MHz. For two nodes separated by millimeter distances, propagation losses are negligible and  $\kappa_{\rm bd}/\kappa_{\rm gd} \approx 5\%$  captures well all intrinsic phonon losses during the transfer. We then find that for realistic undesired phonon losses  $\kappa_{\rm bd}/\kappa_{\rm gd} \approx 5\%$  and  $\sigma_{\rm nuc}/2\pi =$ 80kHz (such that  $\sigma_{\rm nuc}/\kappa_{\rm gd} \approx 2.5\%$ ) [68], transfer fidelities close to 95% seem feasible. Notably, this could be improved even further using spin-echo techniques such that  $T_2 \approx 10^2 T_2^{\star}$  [66]. Therefore, state transfer fidelities  $\mathcal{F} > 2/3$  as required for quantum communication [77] seem feasible with present technology. Near unit fidelities might be approached from further optimizations of the system's parameters, the cavity design, the control pulses and/or from communication protocols that correct for errors such as phonon losses [78–80]. Once the transfer is complete, the system can be tuned adiabatically into a storage regime which immunizes the qubit against electronic noise and dominant errors from hyperfine interaction with ambient nuclear spins can be mitigated by standard, occasional refocusing of the spins [66, 69]. Alternatively, one could also investigate silicon dots: while this setup requires a more sophisticated hetero-structure including some piezo-electric layer (as studied experimentally in Ref. [40]), it potentially benefits from prolonged dephasing times  $T_2^* > 100 \mu s$  [81], since nuclear spins are largely absent in isotopically purified <sup>28</sup>Si.

## VI. SUMMARY & OUTLOOK

In summary, we have proposed and analyzed SAW phonons in piezo-active materials (such as GaAs) as a universal quantum transducer that allows to convert quantum information between stationary and propagating realizations. We have shown that a sound-based quantum information architecture based on SAW cavities and waveguides is very versatile, bears striking similarities to cavity QED and can serve as a scalable mediator of long-range spin-spin interactions between a variety of qubit implementations, allowing for faithful quantum state transfer between remote qubits with existing experimental technology. The proposed combination of techniques and concepts known from quantum optics and quantum information, in conjunction with the technological expertise for SAW devices, is likely to lead to further, rapid theoretical and experimental progress.

Finally, we highlight possible directions of research going beyond our present work: First, since our scheme is not specific to any particular qubit realization, novel hybrid systems could be developed by embedding dissimilar systems such as quantum dots and superconducting qubits into a common SAW architecture. Second, our setup could also be used as a transducer between *differ*ent propagating quantum systems such as phonons and photons. Light can be coupled into the SAW circuit via (for example) NV-centers or self-assembled quantum dots and structures guiding both photons and SAW phonons have already been fabricated experimentally [38, 39]. Finally, the SAW architecture opens up a novel, on-chip test-bed for investigations reminiscent of quantum optics, bringing the highly developed toolbox of quantum optics and cavity-QED to the widely anticipated field of quantum acoustics [11, 16, 17, 82]. Potential applications include quantum simulation of many-body dynamics [83], quantum state engineering (yielding for example squeezed states of sound), quantum-enhanced sensing, sound detection, and sound-based material analysis.

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#### Appendix A: Classical Description of Nonpiezoelectric Surface Acoustic Waves

In this Appendix, we review the general (classical) theoretical framework describing SAW in cubic lattices, such as diamond or GaAs. We derive an analytical solution for propagation in the [110] direction. The latter is of particular interest in piezoelectric systems. The classical description of SAW is explicitly shown here to make our

	$c_{11}$	$c_{12}$	$c_{44}$	$ ho[{ m kg/m}^3]$	$e_{14}$
Diamond	107.9	12.4	57.8	3515	0
GaAs	12.26	5.71	6.00	5307	0.157

Table II: Material properties [25] for both diamond and GaAs. The elastic tensor  $\underline{c}$  has three independent parameters, given in units of  $[10^{10} \text{N/m}^2]$ , while the piezoelectric tensor  $\underline{e}$  has a single independent parameter  $e_{14}$  for cubic materials (units of  $\text{C/m}^2$ ).

work self-contained, but follows standard references such as Refs.[25].

*Wave equation.*—The propagation of acoustic waves (bulk and surface waves) in a solid is described by the equation

$$\rho \ddot{u}_i(\mathbf{x}, t) = \frac{\partial T_{ij}}{\partial x_j},\tag{A1}$$

where **u** denotes the displacement vector with  $u_i$  being the displacement along the cartesian coordinate  $\hat{x}_i$  ( $\hat{x}_1 = \hat{x}, \hat{x}_2 = \hat{y}, \hat{x}_3 = \hat{z}$ ),  $\rho$  gives the mass density and T is the stress tensor;  $T_{ij}$  is the *i*th component of force per unit area perpendicular to the  $\hat{x}_j$ -axis. Moreover, **x** is the cartesian coordinate vector, where in the following we assume a material with infinite dimensions in  $\hat{x}, \hat{y}$ , and a surface perpendicular to the  $\hat{z}$ -direction at z = 0. The stress tensor obeys a generalized Hooke's law (stress is linearly proportional to strain)

$$T_{ij} = c_{ijkl} u_{kl},\tag{A2}$$

where the strain tensor is defined as

$$u_{kl} = \frac{1}{2} \left( \frac{\partial u_k}{\partial x_l} + \frac{\partial u_l}{\partial x_k} \right).$$
(A3)

Using the symmetry  $c_{ijkl} = c_{ijlk}$ , in terms of displacements we find

$$T_{ij} = c_{ijkl} \frac{\partial u_k}{\partial x_l},\tag{A4}$$

such that Eq.(A1) takes the form of a set of three coupled wave equations

$$\rho \ddot{u}_i(\mathbf{x}, t) - c_{ijkl} \frac{\partial^2 u_k}{\partial x_i \partial x_l} = 0.$$
 (A5)

The elasticity tensor  $\underline{c}$  obeys the symmetries  $c_{ijkl} = c_{jikl} = c_{ijlk} = c_{klij}$  and is largely defined by the crystal symmetry.

Mechanical boundary condition.—The free surface at z = 0 is stress free (no external forces are acting upon it), such that the three components of stress across z = 0 shall vanish, that is  $T_{13} = T_{23} = T_{33} = 0$ . This results in the boundary conditions

$$T_{i\hat{z}} = c_{i\hat{z}kl} \frac{\partial u_k}{\partial x_l} = 0 \quad \text{at } z = 0.$$
 (A6)

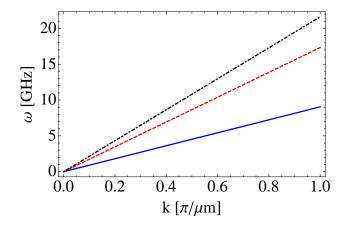


Figure 5: (color online). Dispersion relation  $\omega_n = v_n k$  of the three (n = 1, 2, 3) Rayleigh-type SAW modes for propagation along  $\hat{x}' || [110]$ . If not stated otherwise, we refer to the the lowest frequency solution as the SAW mode (solid line).

Cubic lattice.—For a cubic lattice (such as GaAs or diamond) the elastic tensor  $c_{ijkl}$  has three independent elastic constants, generally denoted by  $c_{11}, c_{12}$ , and  $c_{44}$ ; compare Tab.II. Taking the three direct two-fold axes as the coordinate axes, the wave equations then read

$$\rho \frac{\partial^2 u_x}{\partial t^2} = c_{11} \frac{\partial^2 u_x}{\partial x^2} + c_{44} \left[ \frac{\partial^2 u_x}{\partial y^2} + \frac{\partial^2 u_x}{\partial z^2} \right] + (c_{12} + c_{44}) \left[ \frac{\partial^2 u_y}{\partial x \partial y} + \frac{\partial^2 u_z}{\partial x \partial z} \right], \quad (A7)$$

(and cyclic permutations) while the mechanical boundary conditions can be written as

$$T_{13} = c_{44} \left( \frac{\partial u_z}{\partial x} + \frac{\partial u_x}{\partial z} \right) = 0,$$
 (A8)

$$T_{23} = c_{44} \left( \frac{\partial u_z}{\partial y} + \frac{\partial u_y}{\partial z} \right) = 0,$$
 (A9)

$$T_{33} = c_{11}\frac{\partial u_z}{\partial z} + c_{12}\left(\frac{\partial u_x}{\partial x} + \frac{\partial u_y}{\partial y}\right) = 0, \quad (A10)$$

at z = 0. In the following we seek for solutions which propagate along the surface with a wavevector  $\mathbf{k} = k(l\hat{x} + m\hat{y})$ , where  $l = \cos(\theta)$ ,  $m = \sin(\theta)$  and  $\theta$  is the angle between the  $\hat{x}$ -axis and  $\mathbf{k}$ . Following Ref.[84], we make the ansatz

$$\begin{pmatrix} u_x \\ u_y \\ u_z \end{pmatrix} = \begin{pmatrix} U \\ V \\ W \end{pmatrix} e^{-kqz} e^{ik(lx+my-ct)}, \qquad (A11)$$

where the decay constant q describes the exponential decay of the surface wave into the bulk and c is the phase velocity. Plugging this ansatz into the mechanical wave equations can be rewritten as  $\mathcal{M}\mathbf{A} = 0$ , where

$$\mathcal{M} = \begin{pmatrix} c_{11}l^2 + c_{44} \left(m^2 - q^2\right) - \rho c^2 & lm \left(c_{12} + c_{44}\right) & lq \left(c_{12} + c_{44}\right) \\ lm \left(c_{12} + c_{44}\right) & c_{11}m^2 + c_{44} \left(l^2 - q^2\right) - \rho c^2 & mq \left(c_{12} + c_{44}\right) \\ lq \left(c_{12} + c_{44}\right) & mq \left(c_{12} + c_{44}\right) & c_{11}q^2 - c_{44} + \rho c^2 \end{pmatrix},$$
(A12)

as

$$(u_x, u_y, iu_z) = \sum_{r=1,2,3} (\xi_r, \eta_r, \zeta_r) K_r e^{-kq_r z} e^{ik(lx+my-ct)},$$
(A13)

where, for any  $q_r = q_r(c, \theta)$ , the ratios of the amplitudes can be calculated according to

$$K_r = \frac{U_r}{\xi_r} = \frac{V_r}{\eta_r} = \frac{iW_r}{\zeta_r},$$
 (A14)

where we have introduced the quantities

$$\xi_{r} = \begin{vmatrix} c_{11}m^{2} + c_{44} \left( l^{2} - q_{r}^{2} \right) - \rho c^{2} & mq_{r} \left( c_{12} + c_{44} \right) \\ mq_{r} \left( c_{12} + c_{44} \right) & c_{11}q_{r}^{2} - c_{44} + \rho c^{2} \end{vmatrix},$$
  
$$\eta_{r} = \begin{vmatrix} mq_{r} \left( c_{12} + c_{44} \right) & lm \left( c_{12} + c_{44} \right) \\ c_{11}q_{r}^{2} - c_{44} + \rho c^{2} & lq_{r} \left( c_{12} + c_{44} \right) \end{vmatrix},$$
(A15)

and  $\mathbf{A} = (U, V, iW)$ . Nontrivial solutions for this homogeneous set of equations can be found if the determinant of  $\mathcal{M}$  vanishes, resulting in the so-called *secular equation* det  $(\mathcal{M}) = 0$ . The secular equation is of sixth order in q; as all coefficients in the secular equation are real, there are, in general, three complex-conjugate roots  $q_1^2, q_2^2, q_3^2$ , with the phase velocity c and propagation direction  $\theta$  as parameters. If the medium lies in the half space z > 0, the roots with negative real part will lead to a solution which does not converge as  $z \to \infty$ . Thus, only the roots which lead to vanishing displacements deep in the bulk are kept. Then, the most general solution can be written as a superposition of surface waves with allowed  $q_r$  values and

$$\zeta_r = \begin{vmatrix} lm \left( c_{12} + c_{44} \right) & c_{11}m^2 + c_{44} \left( l^2 - q_r^2 \right) - \rho c^2 \\ lq_r \left( c_{12} + c_{44} \right) & mq_r \left( c_{12} + c_{44} \right) \end{vmatrix}$$
(A16)

Note that for each root  $q_r$  and displacement  $u_i$  there is an associated amplitude. The phase velocity c, however, is the same for every root  $q_r$ , and needs to be determined from the mechanical boundary conditions as described below. Similarly to the acoustic wave equations, the boundary conditions can be rewritten as  $\mathcal{B}(K_1, K_2, K_3) = 0$ , where the boundary condition matrix  $\mathcal{B}$  is

$$\mathcal{B} = \begin{pmatrix} l\zeta_1 - q_1\xi_1 & l\zeta_2 - q_2\xi_2 & l\zeta_3 - q_3\xi_3 \\ m\zeta_1 - q_1\eta_1 & m\zeta_2 - q_2\eta_2 & m\zeta_3 - q_3\eta_3 \\ l\xi_1 + m\eta_1 + aq_1\zeta_1 & l\xi_2 + m\eta_2 + aq_2\zeta_2 & l\xi_3 + m\eta_3 + aq_3\zeta_3 \end{pmatrix},$$
(A17)

with  $a = c_{11}/c_{12}$ . Again, nontrivial solutions are found for det  $(\mathcal{B}) = 0$ . The requirements det  $(\mathcal{M}) = 0$ , det  $(\mathcal{B}) = 0$  together with Eq.(A14) constitute the formal solution of the problem [84]; det  $(\mathcal{M}) = 0$  and det  $(\mathcal{B}) = 0$ may be seen as determining  $c^2$  and  $q^2$ , and Eq.(A14) then gives the the ratios of the components of the displacement. In the following, we discuss a special case where one can eliminate the q-dependence in det  $(\mathcal{B}) = 0$ , leading to an explicit, analytically simple equation for the phase velocity c, which depends only on the material properties.

Propagation in [110] direction.—The wave equations simplify for propagation in high-symmetry directions. Here, we consider propagation in the [110]-direction, for which  $l = m = 1/\sqrt{2}$ ; we define the diagonal as  $\hat{x}' = (\hat{x} + \hat{y})/\sqrt{2}$ . Subtracting the second row from the first in  $\mathcal{M}$ , one finds that the common factor  $(c_{11} - c_{12})/2 - c_{44}q^2 - \rho c^2$  divides through the first row, which then becomes (1, -1, 0). Thus, U = V and the wave equations can be simplified to  $\mathcal{M}_{110}(U, iW) = 0$ , where

$$\mathcal{M}_{110} = \begin{pmatrix} c_{11}' - \rho c^2 - c_{44} q^2 & \frac{q}{\sqrt{2}} (c_{12} + c_{44}) \\ \sqrt{2}q (c_{12} + c_{44}) & c_{11}q^2 - c_{44} + \rho c^2 \end{pmatrix},$$
(A18)

with  $c'_{11} = (c_{11} + c_{12} + 2c_{44})/2$ . Then, the secular equation det  $(\mathcal{M}_{110}) = 0$  is found to be

$$(c'_{11} - \rho c^2 - c_{44}q^2) (c_{44} - \rho c^2 - c_{11}q^2) + (c_{12} + c_{44})^2 q^2 = 0, (A19)$$

yielding the roots  $q_1^2, q_2^2$ . We choose the roots commensurate with the convergence condition yielding the general ansatz

$$\begin{pmatrix} u_{x'} \\ iu_z \end{pmatrix} = \sum_{r=1,2} \begin{pmatrix} U'_r \\ iW_r \end{pmatrix} e^{-kq_r z} e^{ik(x'-ct)}.$$
(A20)

with  $u_x = u_y = u_{x'}/\sqrt{2}$ . The amplitude ratios  $\gamma'_r = iW_r/U'_r$  can be obtained from the kernel of  $\mathcal{M}$  as

$$\gamma_r' = q_r \frac{c_{12} + c_{44}}{c_{44} - c_{11} \left( X + q_r^2 \right)},$$
 (A21)

where  $X = \rho c^2/c_{11}$ . In the coordinate system  $\{\hat{x}', \hat{z}\}$ , the mechanical boundary conditions read

$$\frac{\partial u_z}{\partial x'} + \frac{\partial u_{x'}}{\partial z} = 0, \quad (z = 0)$$
 (A22)

$$c_{12}\frac{\partial u_{x'}}{\partial x'} + c_{11}\frac{\partial u_z}{\partial z} = 0. \quad (z=0)$$
(A23)

For the ansatz given in Eq.(A20), they can be reformulated as  $\mathcal{B}_{110}(U'_1, U'_2) = 0$  with

$$\mathcal{B}_{110} = \begin{pmatrix} \gamma_1' - q_1 & \gamma_2' - q_2 \\ 1 + \frac{c_{11}}{c_{12}} q_1 \gamma_1' & 1 + \frac{c_{11}}{c_{12}} q_2 \gamma_2' \end{pmatrix}.$$
 (A24)

The requirement det  $(\mathcal{B}_{110}) = 0$  can be written as

$$q_1 \left[ c_{12} + \rho c^2 + c_{11} q_1^2 \right] \left[ c_{12} \left( c_{44} - \rho c^2 \right) + c_{11} c_{44} q_2^2 \right] - q_2 \left[ c_{12} + \rho c^2 + c_{11} q_2^2 \right] \left[ c_{12} \left( c_{44} - \rho c^2 \right) + c_{11} c_{44} q_1^2 \right] = 0$$

From the symmetry of this equation it is clear that one can remove a factor  $(q_1 - q_2)$  leading to

$$c_{12}\left(\frac{c_{12}}{c_{11}} + X\right)\left(\frac{c_{44}}{c_{11}} - X\right) + c_{44}q_1^2q_2^2 + c_{12} \times \left(\frac{c_{44}}{c_{11}} - X\right)\left(q_1^2 + q_2^2 + q_1q_2\right) - c_{44}q_1q_2\left(\frac{c_{12}}{c_{11}} + X\right) = 0.$$

Using simple expressions for  $q_1^2 q_2^2$  and  $q_1^2 + q_2^2$  obtained from Eq.(A19), one arrives at the following explicit equation for the wave velocity c [25, 84]

$$\left(1 - \frac{c_{11}}{c_{44}}X\right) \left(\frac{c_{11}c_{11}' - c_{12}^2}{c_{11}^2} - X\right)^2 = X^2 \left(\frac{c_{11}'}{c_{11}} - X\right),$$
(A25)

which is cubic in  $X = \rho c^2/c_{11}$ . If not stated otherwise, we consider the mode with the lowest sound velocity, referred to as Rayleigh mode; compare Fig.5.

Using the secular equation given in Eq.(A19) and the mechanical boundary conditions, the ansatz given in Eq.(A20) can be simplified as follows: The roots compatible with convergence in the bulk are complex conjugate,

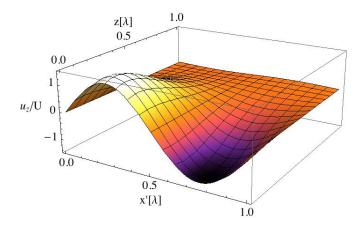


Figure 6: (color online). Depth dependence of the (normalized) vertical displacement  $u_z/U$  along  $\hat{x}'||$  [110] for a Rayleigh surface acoustic wave propagating on a (001) GaAs crystal. The acoustic amplitude decays away from the surface into the bulk on a characteristic length scale approximately given by the SAW wavelength  $\lambda = 2\pi/k \approx 1\mu m$ .

i.e.  $q \equiv q_1 = q_2^*$ , and therefore  $\gamma \equiv \gamma'_1 = \gamma_2^*$ . Then, using the first row in the boundary condition matrix [compare Eq.(A24)], we can deduce

$$U_1' = Ue^{-i\varphi}, \quad U_2' = Ue^{i\varphi}, \tag{A26}$$

where

$$e^{-2i\varphi} = -\frac{\gamma^* - q^*}{\gamma - q}.$$
 (A27)

In summary, we find the following solution [25]

$$u_{x'} = U \left( e^{-qkz - i\varphi} + \text{h.c.} \right) e^{ik(x' - ct)},$$
  

$$iu_z = U \left( \gamma e^{-qkz - i\varphi} + \text{h.c.} \right) e^{ik(x' - ct)}, \quad (A28)$$

where the material-dependent parameters c, q,  $\gamma$  and  $\varphi$ are determined by Eq.(A25), Eq.(A19), Eq.(A21) and Eq.(A25), respectively. For the GaAs parameters given in Tab.II, we get c = 2878m/s, q = 0.5 + 0.48i,  $\gamma = -0.68+1.16i$  and  $\varphi = 1.05$ , respectively. The corresponding (normalized) transversal displacement is displayed in Fig.6.

## Appendix B: Surface Acoustic Waves In Piezoelectric Materials

In a piezoelectric material, elastic and electromagnetic waves are coupled. In principle, the field distribution can be found only by solving simultaneously the equations of both Newton and Maxwell. The corresponding solutions are hybrid elasto-electromagnetic waves, i.e., elastic waves with velocity  $v_s$  accompanied by electric fields, and electromagnetic waves with velocity  $c \approx 10^5 v_s$  accompanied by mechanical strains. For the first type of wave, the magnetic field is negligible, because it is due to an electric field traveling with a velocity  $v_s$  much slower than the speed of light c; therefore, one can approximate Maxwell's equations as  $\nabla \times \mathbf{E} = -\partial \mathbf{B}/\partial t \approx 0$ , giving  $\mathbf{E} = -\nabla \phi$ . Thus, the propagation of elastic waves in a piezoelectric material can be described within the quasi-static approximation, where the electric field is essentially static compared to electromagnetic fields [26]. The potential  $\phi$  and the associated electric field are not electromagnetic in nature but rather a component of the predominantly mechanical wave propagating with velocity  $v_s$ .

## 1. General Analysis

Wave equation.—The basic equations that govern the propagation of acoustic waves in a piezoelectrical material connect the mechanical stress T and the electrical displacement  $\mathbf{D}$  with the mechanical strain and the electrical field. The coupled constitutive equations are

$$T_{ij} = c_{ijkl} \frac{\partial u_k}{\partial x_l} + e_{kij} \frac{\partial \phi}{\partial x_k},$$
  

$$D_i = -\epsilon_{ij} \frac{\partial \phi}{\partial x_j} + e_{ijk} \frac{\partial u_j}{\partial x_k},$$
(B1)

where e with  $(e_{ijk} = e_{ikj})$  and  $\epsilon$  are the piezoelectric and permittivity tensor, respectively. Here, Hooke's law is extended by the additional stress term due to the piezoelectric effect, while the equation for the displacement  $D_i$ includes the polarization produced by the strain. Therefore, Newton's law becomes

$$\rho \ddot{u}_i = c_{ijkl} \frac{\partial^2 u_k}{\partial x_j \partial x_l} + e_{kij} \frac{\partial^2 \phi}{\partial x_j \partial x_k}.$$
 (B2)

For an insulating solid, the electric displacement  $D_i$  must satisfy Poisson's equation  $\partial D_i / \partial x_i = 0$  which yields

$$e_{ijk}\frac{\partial^2 u_j}{\partial x_i \partial x_k} - \epsilon_{ij}\frac{\partial^2 \phi}{\partial x_i \partial x_j} = 0, \quad z > 0$$
 (B3)

$$\Delta \phi = 0, \quad z > 0. \tag{B4}$$

Mechanical boundary conditions.—In the presence of piezoelectric coupling the mechanical boundary conditions [compare Eq.(A6)] generalize to

$$T_{i\hat{z}} = c_{i\hat{z}kl}\frac{\partial u_k}{\partial x_l} + e_{ki\hat{z}}\frac{\partial \phi}{\partial x_k} = 0 \quad \text{at } z = 0.$$
(B5)

Using the symmetries  $c_{ijkl} = c_{jikl}$  and  $e_{kij} = e_{kji}$  it is easy to check that this is equivalent to Eq.(41) in Ref.[25].

*Electric boundary condition.*—In addition to the stressfree boundary conditions, piezoelectricity introduces an electric boundary condition: The normal component of the electric displacement needs to be continuous across the surface [38], that is

$$D_z (z = 0^+) = D_z (z = 0^-),$$
 (B6)

where by definition  $D_z = e_{\hat{z}jk} \partial u_j / \partial x_k - \epsilon_{\hat{z}j} \partial \phi / \partial x_j$ . Outside of the medium (z < 0), we assume vacuum; thus,  $D_z = \epsilon_0 E_z = -\epsilon_0 \partial \phi_{\text{out}} / \partial z$ , where the electrical potential has to satisfy Poisson's equation  $\Delta \phi_{\text{out}} = 0$ . The ansatz

$$\phi_{\rm out} = A_{\rm out} e^{ik(x'-ct)} e^{\Omega kz} \tag{B7}$$

gives  $\Delta \phi_{\text{out}} = (-k^2 + \Omega^2 k^2) \phi_{\text{out}} = 0$ . Thus, for proper convergence far away from the surface  $z \to -\infty$ , we take the decay constant  $\Omega = 1$ ; accordingly, the electrical potential decays exponentially into the vacuum above the surface on a typical length scale given by the SAW wavelength  $\lambda = 2\pi/k \approx 1\mu$ m. Therefore, for the electrical displacement outside of the medium, we find  $D_z = -\epsilon_0 k\phi$ . Lastly, the electrical potential has to be continuous across the surface [25], i.e.,

$$\phi(z=0^+) = \phi_{\text{out}}(z=0^-),$$
 (B8)

which allows us to determine the amplitude  $A_{out}$ . In summary, Eq.(B6) ca be rewritten as

$$\left. \left( e_{\hat{z}jk} \partial u_j / \partial x_k - \epsilon_{\hat{z}j} \partial \phi / \partial x_j + \epsilon_0 k \phi \right) \right|_{z=0} = 0.$$
 (B9)

#### 2. Cubic lattice

Cubic lattice.—For a cubic, piezoelectric system there is only one independent nonzero component of the piezoelectric tensor called  $e_{14}$  [25, 26]. With this piezoelectric coupling, the wave equations are given by four coupled partial differential equations

$$\rho \frac{\partial^2 u_x}{\partial t^2} = c_{11} \frac{\partial^2 u_x}{\partial x^2} + c_{44} \left[ \frac{\partial^2 u_x}{\partial y^2} + \frac{\partial^2 u_x}{\partial z^2} \right]$$
(B10)

$$+ (c_{12} + c_{44}) \left[ \frac{\partial^2 u_y}{\partial x \partial y} + \frac{\partial^2 u_z}{\partial x \partial z} \right] + 2e_{14} \frac{\partial^2 \phi}{\partial y \partial z},$$
  

$$\epsilon \triangle \phi = 2e_{14} \left[ \frac{\partial^2 u_x}{\partial y \partial z} + \frac{\partial^2 u_y}{\partial x \partial z} + \frac{\partial^2 u_z}{\partial x \partial y} \right], \quad (B11)$$

and cyclic for  $u_y$  and  $u_z$ . Here,  $\triangle$  is the Laplacian and  $\epsilon$  is the dielectric constant of the medium. For a cubic lattice, the *mechanical boundary conditions* at z = 0 explicitly read

$$T_{13} = c_{44} \left( \frac{\partial u_z}{\partial x} + \frac{\partial u_x}{\partial z} \right) + e_{14} \frac{\partial \phi}{\partial y} = 0, \quad (B12)$$

$$T_{23} = c_{44} \left( \frac{\partial u_z}{\partial y} + \frac{\partial u_y}{\partial z} \right) + e_{14} \frac{\partial \phi}{\partial x} = 0, \quad (B13)$$

$$T_{33} = c_{11}\frac{\partial u_z}{\partial z} + c_{12}\left(\frac{\partial u_x}{\partial x} + \frac{\partial u_y}{\partial y}\right) = 0, \quad (B14)$$

while the *electrical boundary condition* [compare the general relation in Eq.(B9)] leads to

$$\left[e_{14}\left(\frac{\partial u_x}{\partial y} + \frac{\partial u_y}{\partial x}\right) - \epsilon \frac{\partial \phi}{\partial z} + \epsilon_0 k \phi\right]_{z=0} = 0.$$
(B15)

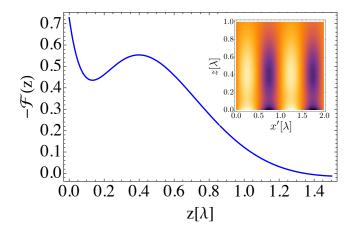


Figure 7: (color online). The dimensionless function  $\mathcal{F}(z)$  determines the decay of the electrical potential away from the surface into the bulk; the characteristic length scale is approximately set by the SAW wavelength  $\lambda = 2\pi/k \approx 1\mu$ m. Inset: Density plot of the (normalized) electric potential Re  $[\phi]/\phi_0 = -\mathcal{F}(kz)\sin(kx'-\omega t)$  along  $\hat{x}'||$  [110] for a Rayleigh surface acoustic wave propagating on a (001) GaAs crystal at t = 0.

In general, the wave equations can be formulated into a  $4 \times 4$  matrix  $\mathcal{M}$ ; the condition det  $\mathcal{M} = 0$  can then used to find the four decay constants. In addition, the mechanical and electrical boundary conditions can be recast to a  $4 \times 4$  boundary condition matrix  $\mathcal{B}$ , from which one can deduce the allowed phase velocities of the piezoelectric SAW by solving det  $\mathcal{B} = 0$ .

Perturbative treatment.—For materials with weak piezoelectric coupling (such as GaAs), the properties of surface acoustic waves are primarily determined by the elastic constants and density of the medium. Then, within a perturbative treatment of the piezoelectric coupling, one can obtain analytical expressions for the strain and piezoelectric fields. Here, we summarize the results for SAWs propagating along  $\hat{x}'||[110]$  of the  $\hat{z}||[001]$  surface following Refs.[25, 27]. Since the piezoelectric coupling  $e_{14}$  is small, it follows from Eq.(B11) that  $\phi$  will be order  $e_{14}$  smaller than the mechanical displacements u, that is

$$\phi \sim \frac{e_{14}}{\epsilon}u.$$
 (B16)

This results in additional terms in the wave equations that are of order  $\sim e_{14}^2/\epsilon \approx 10^8 \text{N/m}^2$ . Since the elastic constants are 2 to 3 orders of magnitude bigger than this piezoelectric term, the wave equations Eqs.(B10), and (cyclic versions for  $u_y, u_z$ ) will be solved by the nonpiezoelectric solution with corrections only at order  $e_{14}^2$ . The nonpiezoelectric solution derived in detail in Sec. A can be summarized as

$$u_{x'} = 2U \operatorname{Re} \left[ e^{-qkz - i\varphi} \right] e^{ik\left(x' - vt\right)},$$
  

$$u_{y'} = 0,$$
  

$$u_{z} = -2iU \operatorname{Re} \left[ \gamma e^{-qkz - i\varphi} \right] e^{ik\left(x' - vt\right)}, \quad (B17)$$

where the sound velocity v for the Rayleigh-mode follows from the smallest solution of

$$(c_{44} - \rho v^2) (c_{11}c_{11}' - c_{12}^2 - c_{11}\rho v^2)^2 = c_{11}c_{44}\rho^2 v^4 (c_{11}' - \rho v^2)$$
(B18)

with  $c'_{11} = c_{44} + (c_{11} + c_{12})/2$ . The decay constant q is a solution of

$$(c'_{11} - \rho v^2 - c_{44}q^2) (c_{44} - \rho v^2 - c_{11}q^2) + q^2 (c_{12} + c_{44})^2 = 0$$
(B19)

Lastly, the parameters  $\gamma$ ,  $\varphi$  can be obtained from

$$\gamma = \frac{(c_{12} + c_{44}) q}{c_{44} - c_{11}q^2 - \rho v^2}, \qquad e^{-2i\varphi} = -\frac{\gamma^* - q^*}{\gamma - q}.$$
 (B20)

Now, based on the nonpiezoelectric solution given in Eq.(B17), the potential  $\phi$  is constructed such that both the wave equation in Eq.(B11) and the electrical boundary condition in Eq.(B15) are solved. In the  $\{\hat{x}', \hat{y}', \hat{z}\}$  coordinate system they read explicitly

$$\epsilon \triangle \phi = e_{14} \left( 2 \frac{\partial^2 u_{x'}}{\partial x' \partial z} + \frac{\partial^2 u_z}{\partial x' \partial x'} \right), \tag{B21}$$

$$0 = \left(\epsilon_0 k\phi + e_{14} \frac{\partial u_{x'}}{\partial x'} - \epsilon \frac{\partial \phi}{\partial z}\right)\Big|_{z=0}.$$
 (B22)

One can readily check that this is achieved by the form proposed in Ref.[25, 27]

$$\phi = \begin{cases} i\phi_0 \mathcal{F}(kz) e^{ik(x'-vt)}, & z > 0\\ A_{\text{out}} e^{kz} e^{ik(x'-ct)}, & z < 0, \end{cases}$$
(B23)

where  $\phi_0 = (e_{14}/\epsilon) U$  and  $A_{out} = i\phi_0 \mathcal{F}(0)$ . Here, we have introduced the dimensionless function  $\mathcal{F}(kz)$  which determines the length scale on which the electrical potential generated by the SAW decays into the bulk. It is given by

$$\mathcal{F}(kz) = 2 |A_1| e^{-\alpha kz} \cos\left(\beta kz + \varphi + \xi\right) + A_3 e^{-kz},$$
(B24)

with  $A_1 = |A_1| e^{-i\xi}$ ,  $q = \alpha + \beta i$ , and

$$A_{1} = \frac{\gamma - 2q}{q^{2} - 1}, \qquad (B25)$$
$$A_{3} = -\frac{2}{\epsilon + \epsilon_{0}} \left[ \epsilon \cos \varphi + \epsilon \operatorname{Re} \left[ A_{1} q e^{-i\varphi} \right] + \epsilon_{0} \operatorname{Re} \left[ A_{1} e^{-i\varphi} \right] \right]$$

For Al<sub>x</sub>Ga<sub>1-x</sub>As we obtain the following parameter values [compare Ref.[25]]:  $|A_1| \approx 1.59$ ,  $A_3 = -3.1$ ,  $\alpha \approx 0.501$ ,  $\beta \approx 0.472$ ,  $\varphi = 1.06$ , and  $\xi = -0.33$ . The electric potential for this parameter set is shown in Fig.7.

## Appendix C: Mechanical Zero-Point Fluctuation

In this Appendix we provide more detailed calculations and estimates for the mechanical zero-point motion  $U_0$  of a SAW. We show that they agree very well with the simple estimate given in the main text. Finally, we provide

	decay const. $\Omega$	$\gamma =  \gamma   e^{-i\Theta}$	$\varphi$	$v_s[m/s]$	δ
GaAs	0.50 + 0.48i	-0.68 + 1.16i	1.05	2878	1.2
Diamond	0.60 + 0.22i	-1.05 + 0.75i	1.26	11135	0.44

Table III: Derived properties for Rayleigh surface waves, for both GaAs and diamond.

0. details on the material parameters used to obtain the numerical estimates.

Our first approach follows closely the one presented in Ref.[31]. The analysis starts out from the mechanical displacement operator in the Heisenberg picture

$$\hat{\mathbf{u}}(\mathbf{x},t) = \sum_{n} \left[ \mathbf{v}_{n}(\mathbf{x}) a_{n} e^{-i\omega_{n}t} + \text{h.c.} \right].$$
(C1)

To obtain the proper normalization of the displacement profiles, let us assume a single phonon Fock state, that is  $|\Psi\rangle = a_n^{\dagger} |\text{vac}\rangle = |0, \dots, 0, 1_n, 0, \dots\rangle$ , where  $|\text{vac}\rangle = \prod_n |0\rangle_n$  is the phonon vacuum and compute the expectation value of additional field energy above the vacuum  $E_{\text{mech}}$ , defined as twice the kinetic energy, since for a mechanical mode half of the energy is kinetic, the other one potential [31]. We find

$$E_{\text{mech}} = 2\omega_n^2 \int d^3 \mathbf{r} \rho(\mathbf{r}) \, \mathbf{v}_n^*(\mathbf{r}) \cdot \mathbf{v}_n(\mathbf{r}) \qquad (C2)$$

$$= 2\rho V \omega_n^2 \max\left[\left|\mathbf{v}_n\left(\mathbf{r}\right)\right|^2\right], \qquad (C3)$$

where the last equality defines the effective mode-volume for mode n. Setting  $U_0 = \max[|\mathbf{v}_n(\mathbf{r})|]$ , and assuming the phonon energy as  $E_{\text{mech}} = \hbar\omega_n$ , we arrive at the general result for a phonon mode,  $U_0 = \sqrt{\hbar/2\rho V \omega_n}$ ; this confirms the simple estimate given in the main text.

Explicit example.—Next, we provide a calculation based on the exact analytical results derived in Appendix A and B. In what follows, we assume that, in analogy to cavity QED, cavity confinement leads to the quantization  $k_n = n\pi/L_c$ , where  $A = L_c^2$  is the effective quantization area. In a full 3D model,  $A = L_x L_y$  where  $L_y$ is related to the spread of the transverse mode function as discussed (for example) in Refs.[14]. For simplicity, here we take  $L_x = L_y$ . Surface wave resonators can routinely be designed to show only one resonance  $k_0$  [14]. Within this single-mode approximation, based on results derived in Appendix A for a SAW traveling wave, we take the quantized mechanical displacement describing a SAW standing wave along the axis  $\hat{x}' = (110)$  as

$$\hat{u}(x',z) = U_0 \begin{pmatrix} \chi_0(z)\cos(k_0x')\\ 0\\ \zeta_0(z)\sin(k_0x') \end{pmatrix} \begin{bmatrix} a+a^{\dagger} \end{bmatrix}, \quad (C4)$$

Here, the functions  $\chi_0(z)$  and  $\zeta_0(z)$  describe how the SAW decays into the bulk,

$$\chi_0(z) = 2e^{-\Omega_r k_0 z} \cos\left(\Omega_i k_0 z + \varphi\right), \tag{C5}$$

$$\zeta_0(z) = 2 |\gamma| e^{-\Omega_r k_0 z} \cos\left(\Omega_i k_0 z + \varphi + \theta\right), \quad (C6)$$

with material-dependent parameters  $\Omega = \Omega_r + i\Omega_i$ ,  $\gamma = |\gamma| \exp [-i\theta]$  and  $\varphi$ ; numerical values are presented in Table III. We note that for GaAs we find  $\zeta(0)/\chi(0) \approx 1.33$ . This is in very good agreement with the numerical values of  $c_x = |u_x/\phi| = 0.98$  nm/V and  $c_z = |u_z/\phi| = 1.31$  nm/V as given in Ref.[15]. Normalization of the mode-function allows us to determine the parameter  $U_0$ . Performing the integration, we find

$$U_0 = \sqrt{\frac{\Omega_r}{\delta}} \sqrt{\frac{\hbar}{2\rho v_s A}},\tag{C7}$$

where the parameter  $\delta$  depends on the material parameters; see Table III. Using typical material parameters, we obtain for GaAs (diamond)  $\sqrt{\Omega_r/\delta} = 0.64(1.17)$  and  $U_0 \approx 1.2 (1.36) \text{ fm}/\sqrt{A[\mu \text{m}^2]}$ . This is in very good agreement with the numerical values presented in the main text.

Estimates derived from literature.—In Ref.[25], it is shown that the SAW Rayleigh mode studied in Appendix A has a classical energy density  $\mathcal{E}$  (energy per unit surface area) given by

$$\mathcal{E} = kU^2H,\tag{C8}$$

where U is the amplitude of the wave, k the wave vector and H a material-dependent factor which is given as  $H \approx 28.2 \times 10^{10} \text{N/m}^2$  for GaAs. By equating the classical energy of the SAW given by  $\mathcal{E}A$ , where A is the quantization area, with its quantum-mechanical analog  $N_{\text{ph}}\hbar\omega$  ( $N_{\text{ph}}$  is the number of phonons), we can estimate the single phonon displacement  $U_0$  as

$$U_0 = \sqrt{\frac{\hbar\omega}{kHA}} = \sqrt{\frac{\hbar v_s}{HA}} \approx 1.05 \times 10^{-21} \frac{m^2}{\sqrt{A}}, \quad (C9)$$

with  $U = U_0 \sqrt{N_{\text{ph}}}$ . This estimate is also found to be in very good agreement with a result given in Ref.[38] as

$$U_0 = C \sqrt{\frac{2\hbar}{\rho v_s A}} \approx 1.7 \times 10^{-21} \frac{m^2}{\sqrt{A}},\tag{C10}$$

where C is a normalization constant with numerical value  $C \approx 0.45$  for GaAs [38]. Therefore, for an effective mode area of  $L_c = \sqrt{A} = 1 \mu \text{m}$  we find a single phonon displacement of  $U_0 \approx 1 \text{fm}$ . This confirms the estimates given in the main text.

#### **Appendix D: Zero-Point Estimates**

In this Appendix we provide details on piezo-magnetic materials and numerical estimates of the zero-point quantities for several relevant materials. The results are summarized in Tab.IV. The underlying input parameters are given below.

Theoretically, piezo-magnetic materials with a large magneto-strictive effect are typically described in a 1:1

 $\left\| U_0 \left[ \text{fm} \right] \right| s_0 [10^{-9}] \left| \begin{array}{c} \phi_0 \left[ \mu \text{V} \right] \end{array} \right| \left| \begin{array}{c} \xi_0 \left[ \text{V/m} \right] \end{array} \left| \begin{array}{c} B_0 \left[ \mu \text{T} \right] \right| \\ \end{array} \right|$ 

	0 [111]	00[10]	φ0[μ··]	<b>S</b> 0[1/m]	
GaAs	1.9	11.7	3.1	19.2	
$\mathrm{LiNbO}_3$	1.8	11.3	0.9 - 25.8	5.8 - 162.2	—
Quartz	2.75	17.3	2.8 - 12.0	17.3 - 75.4	
Terfenol-D	2.2	13.8		_	2.3
${\rm CoFe_2O_4}$	1.8	11.4		_	6.3
Diamond	1.17	7.4			_

Table IV: Estimates for zero-point fluctuations (mechanical amplitude  $U_0$ , strain  $s_0$ , electrical potential  $\phi_0$ , electric field  $\xi_0$  and magentic field  $B_0$ ) close to the surface  $(d \ll \lambda)$  for typical piezo-electric and piezo-magnetic (magnetostrictive) materials. All values must be multiplied by the universal scaling factor  $1/\sqrt{A [\mu m^2]}$ ; thus, they refer to an effective surface mode area of size  $A = 1\mu m^2$ . Lower (upper) bounds for  $\phi_0$  and  $\xi_0$  comprise minimum (maximum) non-zero element of  $\underline{\epsilon}$ . We have set  $k = 2\pi/\mu m$ . Details on cut-directions and material parameters are given in the text.

correspondence to Eqs.(2) and (3), with the appropriate replacements (using standard notation)  $\mathbf{E} \to \mathbf{H}, \mathbf{D} \to \mathbf{B}, \epsilon_{ij} \to \mu_{ij}$  and  $e_{ijk} \to h_{ijk}$  [32]. Coupling between mechanical and magnetic degrees of freedom is described by the piezomagnetic tensor  $\underline{h}$  which can reach values as high as ~ 700T/strain [35]; for our estimates we have referred to Terfenol-D, where  $h_{15} \approx 167$ T/strain. The magnetic field associated with a single phonon can then be estimated as  $B_0 \approx h_{15}s_0$ , where  $h_{15}$  refers to a typical (non-zero) element of  $\underline{h}$ .

For the piezoelectric materials GaAs,  $LiNbO_3$  and Quartz all material parameters have been obtained from Ref. [26]. Phase velocities for typical cut directions have been used, that is (100)[001] GaAs, Y-Z LiNbO<sub>3</sub> and ST Quartz. For the piezomagnetic (magnetostrictive) materials CoFe<sub>2</sub>O<sub>4</sub> and Terfenol-D all material parameters have been taken from Ref.[34]. We have used the phase velocities of the bulk shear waves given in there as  $v_{\rm sh} = 3.02 \times 10^3 {\rm m/s}$  and  $v_{\rm sh} = 1.19 \times 10^3 {\rm m/s}$  for CoFe<sub>2</sub>O<sub>4</sub> and Terfenol-D, respectively. This gives an conservative estimate for  $U_0$ , since Rayleigh modes have phase velocities that are lower than the ones of bulk modes [14]. For example, in the case of  $CoFe_2O_4$  in Ref. [35] wave velocities for Rayleigh-type surface waves in a piezoelectric-piezomagnetic layered half space are found to be  $v_s \approx 2840 \text{m/s} < v_{\text{sh}}$ .

## **Appendix E: SAW Cavities**

In this Appendix, we present a detailed discussion of the theoretical model describing the SAW resonator.

Typically, a SAW cavity is based on an on-chip distributed Bragg reflector formed by a periodic array of either metal electrodes or grooves etched into the surface; see Fig.1. In such a grating, each strip reflects only weakly, but, for many strips  $N \gg 1$ , the total reflec-

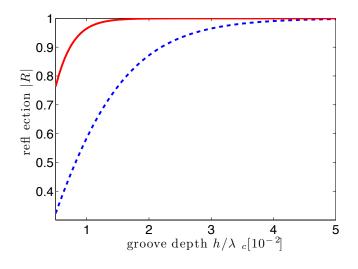


Figure 8: (color online). Total reflection coefficient |R| as a function of the normalized groove-depth  $h/\lambda_c$  for N = 100 (blue dashed) and N = 300 (red solid). Here, w/p = 0.5 and material parameters for LiNbO<sub>3</sub> have been used (see text).

tion |R| can approach unity if the pitch p equals half the wavelength,  $p = \lambda_c/2$ . This Bragg condition defines the center frequency

$$f_c = v_s/2p. \tag{E1}$$

At  $f = f_c$ , the total reflection coefficient is given by

$$|R| = \tanh\left(N\left|r_s\right|\right),\tag{E2}$$

where N is the number of strips and  $r_s$  is the reflection coefficient associated with a single strip [14, 15]. The total reflection coefficient |R| goes to unity in the limit  $N|r_s| \gg 1$ ; see Fig.(8). Typically,  $N \gtrsim 200$ and  $|r_s| \approx (1-2)\%$  [14]. For  $f \approx f_c$ ,  $|r_s|$  increases with the normalized groove depth as  $|r_s| = C_1 h/\lambda_c \sin(\pi w/p) + C_2 (h/\lambda_c)^2 \cos(\pi w/p)$ , with materialdependent pre-factors [37]. For LiNbO<sub>3</sub>,  $C_1 = 0.67$  and  $C_2 = 42$  [37]. As argued in Ref.[37], the first term  $\sim C_1$ is due to a impedance mismatch, while the second one  $\sim C_2$  is due to the stored energy effect.

Due to the distributed nature of the mirror, strong reflection occurs over a fractional bandwidth only, given by  $\delta f/f_c \approx 2|r_s|/\pi$ . In practice, the cavity formed by two reflective gratings can be viewed as an acoustic Fabry-Perot resonator with effective reflection centers, sketched by localized mirrors in Fig.1, situated at some effective penetration distance into the grating, given by  $L_p = \tanh [(N-1)|r_s|] \lambda_c/(4|r_s|) \approx \lambda_c/4|r_s|$ [14, 15, 36]. Therefore, the total effective cavity size along the mirror axis is  $L_c \approx D + 2L_p$ , where D is the physical gap between the gratings; compare Fig.1. For  $N \approx 100-300, h/\lambda_c \approx 2\%$ , we then obtain  $L_c \approx 38\lambda_c$  and  $L_c \approx 42\lambda_c$  for  $D = 0.75\lambda_c$  and  $D = 5.25\lambda_c$ , respectively. In analogy to an optical Fabry-Perot resonator, the mode spacing can then by estimated as  $\Delta f/f_c = \lambda_c/2L_c \approx |r_s|$ . Since this is larger than  $\delta f/f_c$ , SAW resonators can be designed to host a single resonance only [14].

The total decay rate of this resonance  $\kappa$  can be decomposed into four relevant contributions [37],  $\kappa = \kappa_{bk} + \kappa_d +$  $\kappa_m + \kappa_r$ , which includes conversion into bulk modes  $\sim \kappa_{bk}$ , diffraction losses  $\sim \kappa_d$ , internal losses due to material imperfections  $\sim \kappa_m$ , and leakage (radiation) losses due to imperfect mirrors  $\sim \kappa_r$ . The associated Q-factors given by  $Q_i = \omega_c / \kappa_i$ . The desired decay rate is  $\kappa_{\rm gd} = \kappa_r$ , whereas the undesired one is  $\kappa_{bd} = \kappa_{bk} + \kappa_m + \kappa_d$ . Here,  $\kappa_d$  is associated with diffraction losses due to spillover beyond the aperture of the reflector. It can be made negligible by lateral confinement using for example waveguide structures, focusing or etching techniques [14, 38, 39].  $Q_m$  refers to losses due to interaction with thermal phonons, losses due to defects in the material and propagation losses due to contamination [36, 37]. These losses ultimately limit Q: Low temperature experiments on quartz have demonstrated SAW resonators with  $Q_m \times f$  [GHz] > 10<sup>5</sup> [21, 22]. Another source of losses is due to mode-conversion into bulk-modes. Measurements show that  $Q_{bk} = 2\pi N_{\text{eff}} / [C_b (h/\lambda_c)^2]$  with  $N_{\text{eff}} = L_c / \lambda_c$ and a material-dependent pre-factor  $C_b$  [85]; for LiNbO<sub>3</sub> (Quartz),  $C_b = 8.7(10)$ , respectively [85, 86]. Typically,  $\kappa_{bk}$  is found to be negligible for small groove depths,  $h/\lambda_c < 2\%$  [37]. Finally,  $\kappa_r$  arises from leakage through imperfectly reflecting gratings (|R| < 1); in direct analogy to optical Fabry-Perot resonators, the associated Qfactor is given by  $Q_r = 2\pi N_{\text{eff}} / (1 - |R|^2)$ . Assuming negligible diffraction losses (that can be minimized via waveguide-like confinement [14, 42]) and cryostat temperatures, the total *Q*-factor is then given by

$$Q^{-1} = Q_m^{-1} + Q_{bk}^{-1} + Q_r^{-1}.$$
 (E3)

## Appendix F: Charge Qubit Coupled to SAW Cavity Mode

We consider a GaAs charge qubit embedded in a tunnel-coupled double quantum dot (DQD) containing a single electron. In the one-electron regime the single-particle orbital level spacing is on the order of ~ 1meV. Therefore, the system is well described by an effective two-level system: The state of the qubit is set by the position of the electron in the double-well potential, with the logical basis  $|L\rangle$ ,  $|R\rangle$  corresponding to the electron localized in the left (right) orbital. The Hamiltonian describing this system reads

$$H_{\rm ch} = \frac{\epsilon}{2}\sigma^z + t_c\sigma^x,\tag{F1}$$

with the (orbital) Pauli-operators defined as  $\sigma^z = |L\rangle \langle L| - |R\rangle \langle R|$  and  $\sigma^x = |L\rangle \langle R| + |R\rangle \langle L|$ , respectively. In Eq.(5),  $\epsilon$  refers to the level detuning between the dots, while  $t_c$  gives the tunnel coupling. The level splitting between the eigenstates of  $H_{\rm ch}$  is given by  $\Omega = \sqrt{\epsilon^2 + 4t_c^2}$ , with a pure tunnel-splitting of  $\Omega = 2t_c$  at the charge degeneracy point ( $\epsilon = 0$ ); typical parameter values are  $t_c \sim \mu \text{eV}$  and  $\epsilon \sim \mu \text{eV}$ , such that the level splitting  $\Omega \sim \text{GHz}$  lies in the microwave regime. At the charge degeneracy point, where to first order the qubit is insensitive to charge fluctuations  $(d\Omega/d\epsilon = 0)$ , the coherence time has been found to be  $T_2 \approx 10 \text{ns}$  [45].

We now consider a charge qubit as described above inside a SAW resonator with a single resonance frequency  $\omega_c$  close to the qubit's transition frequency,  $\omega_c \approx \Omega$ , that is the regime of small detuning  $\delta = \Omega - \omega_c \approx 0$ ; note that single-resonance SAW cavities can be realized routinely with today's standard techniques [14]. Within this single-mode approximation, the Hamiltonian describing the SAW cavity simply reads

$$H_{\rm cav} = \omega_c a^{\dagger} a, \tag{F2}$$

where  $a^{\dagger}(a)$  creates (annihilates) a phonon inside the cavity. The electrostatic potential associated with this mode is given by  $\phi(\mathbf{x}) = \phi(\mathbf{x}) |a + a^{\dagger}|$ , where the modefunction  $\phi(\mathbf{x})$  can be obtained from the corresponding mechanical mode-function  $\mathbf{w}(\mathbf{x})$  via the relation  $\epsilon \bigtriangleup \phi(\mathbf{x}) = e_{kij} \partial_j \partial_k w_i(\mathbf{x})$ ; here,  $\bigtriangleup$  is the Laplacian,  $e_{kij}$ the piezoelectric tensor and  $\epsilon$  the permittivity of the material. The electron's charge e couples to the phonon induced electrical potential  $\hat{\phi}$ . In second quantization, the piezoelectric interaction reads  $H_{\text{int}} = e \int d\mathbf{x} \, \phi(\mathbf{x}) \, \hat{n}(\mathbf{x})$ , where *e* is the electron's charge,  $\hat{n}(\mathbf{x}) = \sum_{\sigma} \psi_{\sigma}^{\dagger}(\mathbf{x}) \psi_{\sigma}(\mathbf{x})$ is the electron number density operator and  $\psi_{\sigma}^{\dagger}(\mathbf{x})$  creates an electron with spin  $\sigma$  at position x [24]. Since  $\phi$  (x) varies on a micron length-scale which is large compared to the spatial extension  $\sim 40$  nm of the electron's wavefunction in a QD [64], the electron density is approximately given by a delta-function at the center of the corresponding dots. For the DQD system under consideration  $H_{\rm int}$  is then approximately given by  $H_{\text{int}} = e \sum_{i} \hat{\phi}(\mathbf{x}_{i}) n_{i}$ ; here,  $\mathbf{x}_i$  refers to the center of the electronic orbital wavefunction  $\psi_i(\mathbf{x})$  of dot i = L, R. Note that this form of  $H_{\rm int}$  becomes exact if the overlap integral vanishes, that is if  $\int d\mathbf{x} \phi(\mathbf{x}) \psi_L^*(\mathbf{x}) \psi_R(\mathbf{x}) = 0$  is satisfied. As shown below, for a mode-function  $\phi(\mathbf{x})$  of sine-form, this condition maximizes the piezoelectric coupling strength between the electronic DQD system and the phonon mode. For the charge qubit system under consideration coupling to the cavity mode is then described by  $H_{\text{int}} = e \left( a + a^{\dagger} \right) \left[ \phi \left( x_L \right) \left| L \right\rangle \left\langle L \right| + \phi \left( x_R \right) \left| R \right\rangle \left\langle R \right| \right]; \text{ here,}$  $x_i$  refers to the center of the electronic orbital wavefunction  $\varphi_i(\mathbf{x})$  of dot i = L, R and the transverse direction  $\hat{y}$  has been integrated out already. To obtain strong coupling between the qubit and the cavity, we assume a mode profile  $\phi(x) = \varphi_0 \sin(kx)$ , with a node tuned between the two dots, such that  $\phi(x_L) = \varphi_0 \sin(kl/2) = -\phi(x_R)$ ; here, l gives the distance between the two dots. Note that the single phonon amplitude, defined as  $\varphi_0 = \phi_0 \mathcal{F}(kd)$ , with  $\mathcal{F}(kd) \approx 0$  for  $d \gg \lambda$ , accounts for the decay of the SAW into the bulk. For  $\lambda = (0.5 - 1) \,\mu\text{m}$  and a 2DEG (where the DQD is embedded) situated a distance d = 50 nm below the surface, however, the single

phonon amplitude is reduced by a factor of ~ 2 only,  $\varphi_0 \approx (0.45 - 0.52) \phi_0$ ; see Appendix B for details. Then, the coupling between qubit and cavity reads

$$H_{\rm int} = g_{\rm ch} \left( a + a^{\dagger} \right) \otimes \sigma^z, \tag{F3}$$

where the single-phonon coupling strength is

$$g_{\rm ch} = e\phi_0 \mathcal{F}(kd) \sin\left(kl/2\right) \approx \frac{1.5\mu \text{eV}}{\sqrt{A\left[\mu\text{m}^2\right]}}.$$
 (F4)

Here, we have assumed  $\lambda \approx 2l$  such that the geometrical factor  $\sin(\pi l/\lambda) \approx 1$  [46]. In principle, the coupling strength  $g_{\rm ch}$  could be further enhanced by additionally depositing a strongly piezoelectric material such as LiNbO<sub>3</sub> on the GaAs substrate. Moreover, comparison with standard literature shows that the piezoelectric electron-phonon coupling strength can be expressed as  $g_{\rm pe} = \sqrt{P}U_0 \approx e(e_{14}/\epsilon) U_0 = e\phi_0$ , where  $P = (ee_{14}/\epsilon)^2$  is a material parameter quantifying the piezoelectric coupling strength in zinc-blend structures [87, 88]. Using  $P = 5.4 \times 10^{-20} \text{J}^2 \text{m}^{-2}$  for GaAs, the single phonon Rabi frequency can be estimated as  $g_{\rm pe} \approx 2.87 \mu \text{eV}/\sqrt{A[\mu\text{m}^2]}$ . This corroborates our estimate for  $g_{\rm ch}$ .

In summary, the total system can be described by the Hamiltonian  $H = H_{ch} + H_{cav} + H_{int}$ ,

$$H = \frac{\epsilon}{2}\sigma^{z} + t_{c}\sigma^{x} + \omega_{c}a^{\dagger}a + g_{ch}\left(a + a^{\dagger}\right) \otimes \sigma^{z}.$$
 (F5)

This corresponds to the generic Hamiltonian for a qubitresonator system [31]. It is instructive to rewrite H in the eigenbasis of  $H_{ch}$ , given by

$$|+\rangle = \sin \theta |L\rangle + \cos \theta |R\rangle,$$
 (F6)

$$|-\rangle = \cos\theta |L\rangle - \sin\theta |R\rangle,$$
 (F7)

where the mixing angle  $\theta$  is defined via  $\tan \theta = 2t_c/(\epsilon + \Omega)$ . In a rotating wave approximation  $(\delta, g_{\rm ch} \ll \omega_c)$ , *H* then reduces to the well-known Hamiltonian of Jaynes-Cummings form

$$H \approx \delta S^{z} + g_{\rm ch} \frac{2t_c}{\Omega} \left( S^{+}a + S^{-}a^{\dagger} \right), \qquad (F8)$$

where  $\delta = \Omega - \omega_{\rm c}$ ,  $S^z = (|+\rangle \langle +|-|-\rangle \langle -|)/2$  and  $S^{\pm} = |\pm\rangle \langle \mp|$ .

## Appendix G: SAW-Based Cavity QED with Spin Qubits in Double Quantum Dots

In this Appendix, we show in detail how to realize the prototypical Jaynes-Cummings dynamics based on a spin qubit encoded in a double quantum dot (DQD) inside a SAW resonator.

We consider a double quantum dot (in the two-electron regime) coupled to the electrostatic potential generated by a SAW. The system is described by the Hamiltonian

$$H_{\rm DQD} = H_0 + H_{\rm cav} + H_{\rm int},\tag{G1}$$

where  $H_0$ ,  $H_{cav}$  and  $H_{int}$  describe the DQD, the cavity and the electrostatically mediated coupling between them, respectively. In the following, the different contributions are discussed in detail.

*Double Quantum Dot.*—The DQD is modeled by the standard Hamiltonian

$$H_0 = H_C + H_t + H_Z. \tag{G2}$$

Here,  $H_C$  gives the electrostatic energy

$$H_C = \sum_{i,\sigma} \epsilon_i n_{i\sigma} + U \sum_{i=L,R} n_{i\uparrow} n_{i\downarrow} + U_{LR} n_L n_R, \quad (G3)$$

where (due to strong confinement) both the left and right dot are assumed to support a single orbital level with energy  $\epsilon_i (i = L, R)$  only; U and  $U_{LR}$  refer to the on-site and interdot Coulomb repulsion, respectively. As usual,  $n_{i\sigma} = d_{i\sigma}^{\dagger} d_{i\sigma}$  and  $n_i = n_{i\uparrow} + n_{i\downarrow}$  refer to the spin-resolved and total electron number operators, respectively, with the fermionic creation (annihilation) operators  $d_{i\sigma}^{\dagger}(d_{i\sigma})$ creating (annihilating) an electron with spin  $\sigma = \uparrow, \downarrow$  in the orbital i = L, R. We focus on a setting where an applied bias between the two dots approximately compensates the Coulomb energy of two electrons occupying the right dot; that is,  $\epsilon_L \approx \epsilon_R + U - U_{LR}$ . Thus, we restrict ourselves to a region in the stability diagram where only (1,1) and (0,2) charge states are of interest. All levels with (1,1) charge configuration have an electrostatic energy of  $E_{(1,1)} = \epsilon_L + \epsilon_R + U_{LR}$ , while the (0,2) configuration has  $E_{(0,2)} = 2\epsilon_R + U$ . As usual, we introduce the detuning parameter  $\epsilon = \epsilon_L - \epsilon_R + U_{LR} - U$ . In this regime, the relevant electronic levels are defined as  $|T_+\rangle = |\uparrow\uparrow\rangle$ ,  $|T_-\rangle = |\downarrow\downarrow\downarrow\rangle$ ,  $|T_0\rangle = (|\uparrow\downarrow\downarrow\rangle + |\downarrow\uparrow\rangle)/\sqrt{2}$ ,  $|S_{11}\rangle = (|\uparrow\downarrow\rangle - |\downarrow\uparrow\rangle)/\sqrt{2}$  and  $|S_{02}\rangle = d^{\dagger}_{R\uparrow}d^{\dagger}_{R\downarrow}|0\rangle$  with  $|\sigma\sigma'\rangle = d^{\dagger}_{L\sigma}d^{\dagger}_{R\sigma'}|0\rangle.$ 

Next,  $H_t$  describes coherent, spin-preserving interdot tunneling

$$H_t = t_c \sum_{\sigma} d^{\dagger}_{L\sigma} d_{R\sigma} + \text{h.c.}, \qquad (G4)$$

where  $t_c$  is the interdot tunneling amplitude. Lastly,  $H_Z$  accounts for the Zeeman energies,

$$H_Z = g\mu_B \sum_{i=L,R} \mathbf{B}_i \cdot \mathbf{S}_i, \tag{G5}$$

where g is the electron g-factor and  $\mu_B$  the Bohr magneton, respectively. In the presence of a micro-/nanomagnet, the two local magnetic fields  $\mathbf{B}_i$  are inhomogeneous,  $\mathbf{B}_L \neq \mathbf{B}_R$ . We can then write  $\mathbf{B}_i =$  $\mathbf{B}_0 + \mathbf{B}_m(\mathbf{x}_i)$ , where  $\mathbf{B}_0$  is the external homogeneous magnetic field, while  $\mathbf{B}_m(\mathbf{x}_i)$  is the micromagnet slanting field at the location of dot  $\mathbf{x}_i$ . In practice,  $B_0$  is a few Tesla, at least larger than the saturation field of the micromagnet  $B_0 \gtrsim 0.5$ T, while the magnetic gradient  $\Delta B = \|\mathbf{B}_m(\mathbf{x}_R) - \mathbf{B}_m(\mathbf{x}_L)\|$  can reach  $\Delta B \approx 100$ mT, corresponding to an electronic energy scale of  $|g\mu_B \Delta B| \approx$ 

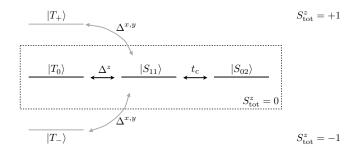


Figure 9: (color online). Illustration of the relevant electronic levels under consideration. The triplet levels with  $S_{\text{tot}}^z \neq 1$  can be tuned off-resonance by applying a sufficiently large homogeneous magnetic field.

 $2\mu \text{eV}$  [89]. Field derivatives realized experimentally are  $\partial B_{\text{m},z}/\partial x \approx 1.5 \text{mT/nm}$ . Alternatively, the magnetic gradient can be realized via the Overhauser field, as experimentally demonstrated for example in Ref.[66].

Note that the Fermi contact hyperfine interaction between electron and nuclear spins reads  $H_{\rm HF} = \sum_i \mathbf{h}_i \cdot \mathbf{S}_i$ . Here,  $\mathbf{h}_i$  is the Overhauser field in QD i = L, R. When treating  $\mathbf{h}_i$  as a classical (random) variable,  $H_{\rm HF}$  is equivalent to  $H_Z$  and thus one can absorb  $\mathbf{h}_i$  into the definition of the magnetic field  $\mathbf{B}_i$  in Eq.(G5); also see Ref.[89].

To facilitate the discussion, we introduce the magnetic sum field  $\mathbf{B} = (\mathbf{B}_L + \mathbf{B}_R)/2$  and the difference field  $\Delta \mathbf{B} = (\mathbf{B}_R - \mathbf{B}_L)/2$ . While **B** conserves the total spin, that is  $[\mathbf{B}(\mathbf{S}_L + \mathbf{S}_R), (\mathbf{S}_L + \mathbf{S}_R)^2] = 0$ , the gradient field  $\Delta \mathbf{B}$  does not. We set the quantization axis  $\hat{z}$  along  $\mathbf{B} = B\hat{z}$ . For sufficiently large magnetic field B the electronic levels with  $S_{\text{tot}}^z = S_L^z + S_R^z \neq 0$  are far detuned and can be neglected for the remainder of the discussion. Therefore, in the following, we restrict ourselves to the  $S_{\text{tot}}^z = 0$  subspace. The components  $\Delta \mathbf{B}^{x,y}$  give rise to transitions out of the (logical) subspace  $S_{\text{tot}}^z = 0$ . Since these processes are assumed to be far off-resonance, they are neglected leaving us with the only relevant magnetic gradient  $\Delta = g\mu_B \Delta \mathbf{B}^z/2$ ; compare also Refs.[65, 66]. For a schematic illustration, compare Fig.9.

In summary, in the regime of interest  $H_0$  simplifies to

$$H_{0} = \frac{t_{c}}{2} \left( |S_{02}\rangle \langle S_{11}| + \text{h.c.} \right) - \epsilon |S_{02}\rangle \langle S_{02}| \quad (G6) -\Delta \left( |T_{0}\rangle \langle S_{11}| + \text{h.c.} \right).$$

The eigenstates of  $H_0$  within the relevant  $S_{\text{tot}}^z = S_L^z + S_R^z = 0$  subspace can be expressed as

$$|l\rangle = \alpha_l |T_0\rangle + \beta_l |S_{11}\rangle + \kappa_l |S_{02}\rangle, \qquad (G7)$$

with corresponding eigenenergies  $\epsilon_l \ (l = 0, 1, 2)$ . The spectrum is displayed in Fig.10. For large negative detuning  $-\epsilon \gg t_c$ , the level  $|2\rangle$  is far detuned, and the electronic subsystem can be simplified to an effective two-level system comprising the levels  $\{|0\rangle, |1\rangle\}$ , that is

$$H_0 \approx \frac{\omega_0}{2} \left( \left| 1 \right\rangle \left\langle 1 \right| - \left| 0 \right\rangle \left\langle 0 \right| \right), \tag{G8}$$

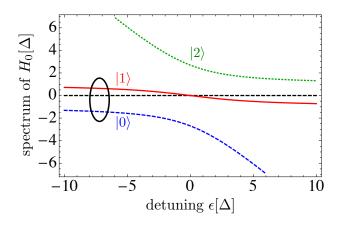


Figure 10: (color online). Spectrum of  $H_0$  for  $t_c = 5\Delta$ . The three eigenstates  $|l\rangle$  are displayed in green dotted (l = 2), red solid (l = 1) and blue dashed (l = 0), respectively. The triplets  $|T_{\pm}\rangle$  are assumed to be far detuned by a large external field and not shown. For large negative detuning  $\epsilon > -t_c$ , the hybridized levels  $\{|0\rangle, |1\rangle\}$  can be used as qubit.

which can be identified with a 'singlet-triplet'-like logical qubit subspace. Here,  $\omega_0 = \epsilon_1 - \epsilon_0$  refers to the qubit's transition frequency. Note that the magnetic gradient causes efficient mixing between  $|T_0\rangle$  and  $|S_{11}\rangle$  for  $\Delta \gtrsim$  $|t_c^2/\epsilon|$ . In the regime of interest, the dominant character of the qubit's levels is  $|1\rangle \approx |\Downarrow \uparrow \rangle$ ,  $|0\rangle \approx |\uparrow \Downarrow \rangle$  (or vice versa) [65] and the transition frequency is approximately  $\omega_0 \approx 2\Delta$ . For  $\Delta \approx 1\mu eV$ , the transition frequency  $\omega_0 =$  $\epsilon_1 - \epsilon_0 \approx 2\mu eV \approx 3 GHz$  matches typical SAW frequencies ~ GHz.

Coupling to SAW phonon mode.—Along the lines of Appendix F, again we consider a SAW resonator with a single relevant confined phonon mode of frequency  $\omega_c$ close to the qubit's transition frequency  $\omega_0$ . For a DQD in the *two*-electron regime, in the basis of Eq.(G6) coupling to the resonator mode can be written as [46]

$$H_{\text{int}} = g_0 \left[ a + a^{\dagger} \right] \otimes \left| S_{02} \right\rangle \left\langle S_{02} \right|, \qquad (G9)$$

where  $g_0 = e\varphi_0 \eta_{\text{geo}}$ . Here,  $\eta_{\text{geo}}$  is a geometrical factor accounting for the DQD's position with respect to the mode-function  $\phi(\mathbf{x})$ ; it is defined according to  $\varphi_0 \eta_{\text{geo}} = \phi(\mathbf{x}_R) - \phi(\mathbf{x}_L)$ . For example, taking a standing wave pattern along  $\hat{x}$  as demonstrated experimentally in Ref. [90], together with a transverse mode function restricting the spread in the  $\hat{y}$ -direction [39, 42], we obtain  $\eta_{\rm geo} = \sin\left(2\pi x_R/\lambda\right) - \sin\left(2\pi x_L/\lambda\right)$ . It takes on its maximum value  $\eta_{opt}$ , when tuning a node of the standing wave at the center between the two dots, that is  $x_R = l/2$ ,  $x_L = -l/2$ ; this gives  $\eta_{\text{opt}} = 2\sin(\pi l/\lambda)$ , where l is the distance between the two dots [46]; as compared to the charge qubit described in Appendix F, there is an additional factor of two, since here we consider a DQD in the two-electron regime, whereas the charge qubit consists of one electron only. For typical parameters (l = 220 nm, l) $\lambda \approx 1.4 \mu m$ ) as used in Ref.[46], we get  $\eta_{opt} \approx 0.95$ , while l = 220 nm,  $\lambda \approx 0.5 \mu$ m leads to the largest possible value

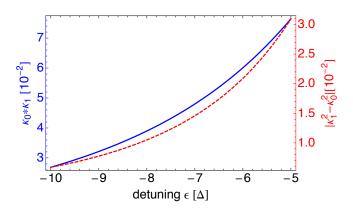


Figure 11: (color online). The product  $\kappa_0 \kappa_1$  directly affects the effective single-phonon Rabi frequency  $g_{\rm QD}/g_0 = \kappa_0 \kappa_1$ [69], while the difference  $|\kappa_1^2 - \kappa_0^2|$  determines the robustness of the qubit against charge noise. Here,  $t_c = 5\Delta$ .

of  $\eta_{\rm opt} \approx 2$ .

In summary, within the effective electronic two-level subspace  $\{|0\rangle, |1\rangle\}$ , the system is described by the Hamiltonian

$$H_{\text{DQD}} = \sum_{l=0,1} \left( \epsilon_l + \kappa_l^2 \hat{V}_{\text{pe}} \right) |l\rangle \langle l| \qquad (G10)$$
$$+ \kappa_0 \kappa_1 \hat{V}_{\text{pe}} (|0\rangle \langle 1| + \text{h.c.}) + \omega_c a^{\dagger} a,$$

where  $\hat{V}_{\rm pe} = g_0 \left[ a + a^{\dagger} \right]$ . Applying a unitary transformation to a frame rotating at the cavity frequency  $\omega_c$  according to  $\tilde{H}_{\rm DQD} = UH_{\rm DQD}U^{\dagger} + i\dot{U}U^{\dagger}$ , with  $U = \exp\left[i\omega_c t \left(a^{\dagger}a + \frac{1}{2}|1\rangle \langle 1| - \frac{1}{2}|0\rangle \langle 0|\right)\right]$ , performing a rotating-wave approximation (RWA), and dropping a global energy shift  $\tilde{\epsilon} = (\epsilon_0 + \epsilon_1)/2$ , we arrive at the effective (time-independent) Hamiltonian of Jaynes-Cummings form

$$\tilde{H}_{\rm DQD} = \bar{\delta}S^z + g_{\rm QD} \left[S^+ a + S^- a^\dagger\right], \qquad (G11)$$

where we have introduced the spin operators  $S^+ = |1\rangle \langle 0|$ and  $S^z = (|1\rangle \langle 1| - |0\rangle \langle 0|) /2$ . Moreover,  $\bar{\delta} = \omega_0 - \omega_c$ is the detuning between the qubit's transition frequency  $\omega_0$  and the cavity frequency  $\omega_c$ , and the effective singlephonon Rabi frequency is defined as

$$g_{\rm QD} = \kappa_0 \kappa_1 \eta_{\rm geo} e \phi_0 \mathcal{F} \left( kd \right) \approx 2\kappa_0 \kappa_1 g_{\rm ch}. \tag{G12}$$

The coupling between the qubit and the cavity mode is mediated by the piezoelectric potential; therefore, it is proportional to the electron's charge e and the singlephonon electric potential  $\phi_0$ . Due to the prolonged decoherence timescales, here we consider an effective (singlettriplet like) spin-qubit rather than a charge qubit, such that the coupling  $g_{\rm QD}$  is reduced by the (small) admixtures with the localized singlet  $\kappa_l = \langle S_{02} | l \rangle$ . Increasing  $\kappa_0 \kappa_1$  leads to a stronger Rabi frequency  $g_{\rm QD}$ , but an increased difference in charge configuration  $|\kappa_1^2 - \kappa_0^2|$ makes the qubit more susceptible to charge noise. For

	cavity size $A[\mu m^2]$	$g_{\rm QD}[{\rm MHz}]$	Q	C
small cavity	1	200	10	4.25
large cavity	500	9	$10^4$	8.5

Table V: Estimates of the single spin cooperativity C for a DQD singlet-triplet qubit with  $T_2^{\star} \approx 100$  ns, in a SAW cavity at gigahertz frequencies  $\omega_c/2\pi \approx 1.5 \text{GHz}$  and cryostat temperatures where  $\bar{n}_{\rm th} \approx 0$  for both a small, low Q and large, high Q SAW-resonator. The coupling strength  $g_{\rm QD}$  could be further increased by additionally depositing a strongly piezoelectric material such as LiNbO<sub>3</sub> on the GaAs substrate and spin-echo (and/or narrowing) techniques allow for dephasing times extended by up to three orders of magnitude [63, 68].

typical numbers ( $t_c \approx 5\mu \text{eV}, \epsilon \approx -7\mu \text{eV}, \Delta \approx 1\mu \text{eV}$ ), we get  $\kappa_0 \kappa_1 \approx 5 \times 10^{-2}, |\kappa_1^2 - \kappa_0^2| \approx 2 \times 10^{-2}$ ; see Fig.11. For  $l \approx 250$  nm,  $\lambda \approx 0.5 \mu$ m, and  $d \approx 50$  nm we can then estimate

$$g_{\rm QD}/\hbar \approx \frac{200 \text{MHz}}{\sqrt{A[\mu \text{m}^2]}}.$$
 (G13)

We take this coupling strength as a conservative estimate. since optimization against the relevant noise sources as done in Ref.[69] yields an optimal point with  $\kappa_0 \kappa_1 \approx$ 0.3 and  $\omega_0/2\pi \approx 1.5$  GHz. Resonance ( $\delta = 0$ ) yields a SAW wavelength of  $\lambda \approx 2\mu m$ ; accordingly, for a fixed dot-to-dot distance l = 250 nm,  $\eta_{\rm geo} \approx 0.76$  (whereas a larger DQD size l = 400nm as used in Ref.[24] gives  $\eta_{\text{geo}} \approx 1.18$ ). For l = 250 nm, d = 50 nm, we then obtain  $g_{\rm QD}/\hbar \approx 600 {\rm MHz}/\sqrt{A[\mu {\rm m}^2]}$ , which is a factor of three larger than the estimate quoted above.

Cooperativity.—In this context, an important figure of merit is the single spin cooperativity [60], C = $g_{\rm QD}^2 T_2 / \kappa (\bar{n}_{\rm th} + 1)$ , where  $\kappa = \omega_c / Q$  is the mechanical damping rate and  $\bar{n}_{\rm th} = 1/(e^{\hbar\omega_c/k_BT} - 1)$  is the equilibrium phonon occupation number at temperature T; here, since  $\hbar\omega_c \gg k_B T$  for cryostatic temperatures,  $\bar{n}_{\rm th} \approx 0$ . For singlet-triplet qubits in lateral QDs,  $T_2^{\star} \approx 100$ ns [63]; using spin-echo techniques, experimentally this has even been extended to  $T_2 = 276 \mu s$ . Even in the absence of spin-echo pulses, with a far-from-optimistic dephasing time  $T_2^{\star} \approx 100$ ns [68], for a moderately small cavity size  $A \approx 100 \mu \mathrm{m}^2$ , a quality factor of Q = 900 is sufficient to reach  $C \approx g_{\rm QD}^2 T_2^* Q / \omega_c \approx 3.8$ . Note that C > 1 allows to perform a quantum gate between two spins mediated by a thermal mechanical mode [9].

Discussion of approximations.—To arrive at the effective Hamiltonian given in Eq.(G11), we have made two essential approximations: (i) first, we have neglected the electronic level  $|2\rangle$  yielding an effective two-level system (TLS), and (ii) second, we have applied a RWA leading to a major simplification of  $H_{DQD}$ ; see Eq.(G11) as compared to Eq.(G10). In order to corroborate these approximations, we now compare exact numerical simulations of the full system where none of the approximations have been applied to the simplified, approximate description described above. While the dynamics of the former is

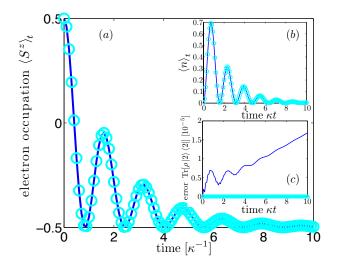


Figure 12: (color online). Exact numerical simulations of the full (blue, solid line) and approximate (cyan circles) Master equations as given in Eqs.(G14) and (G15) respectively. Plots are shown for (a) the electronic inversion  $\langle S^z \rangle_t$ , (b) the cavity occupation  $\langle n \rangle_t$  and (c) the error Tr  $[\rho | 2 \rangle \langle 2 |]$  quantifying the leakage to  $|2\rangle$ . The latter is found to be negligibly small ~ 10<sup>-5</sup>. We have set  $\bar{\delta} = \omega_0 - \omega_c = 0$ . Numerical parameters:  $t_c = 10 \mu \text{eV}, \epsilon = -7 \mu \text{eV}, \Delta = 1 \mu \text{eV}, \eta_{\text{geo}} e \varphi_0 = 5.2 \times 10^{-2} \mu \text{eV}$ such that  $g_{\text{QD}} = 4 \times 10^{-3} \mu \text{eV} \approx 6 \text{MHz}$ . The cavity decay rate is  $\kappa = g_{\rm QD}/2$ , corresponding to  $Q \approx 10^3$ .

described by the Master equation

$$\dot{\rho} = -i \left[ H_0 + H_{\text{cav}} + H_{\text{int}}, \rho \right] + \kappa \mathcal{D} \left[ a \right] \rho, \qquad (\text{G14})$$

with  $H_0$ ,  $H_{cav}$  and  $H_{int}$  given in Eqs.(G6), (F2) and (G9), respectively, the latter is described by a similar Master equation with the coherent Hamiltonian term replaced by the prototypical Jaynes-Cummings Hamiltonian,

$$\dot{\rho} = -i \left[ \bar{\delta} S^z + g_{\text{QD}} \left( S^+ a + S^- a^\dagger \right), \rho \right] + \kappa \mathcal{D} \left[ a \right] \rho, \quad (\text{G15})$$

with  $\rho$  referring to the density matrix of the combined system comprising the DQD and the cavity mode. Here, we have also accounted for decay of cavity phonons out of the resonator with a rate  $\kappa$ , described by the Lindblad term  $\mathcal{D}[a] \rho = a\rho a^{\dagger} - \frac{1}{2} \{a^{\dagger}a, \rho\}$ . As a figure of merit to validate approximation (i) we determine the population of the level level  $|2\rangle$ , that is Tr  $[\rho |2\rangle \langle 2|]$ , describing the undesired leakage out of the logical subspace; ideally, this should be zero. Note that leakage into the triplet levels  $|T_{\pm}\rangle$  could be accounted for along the lines, but they can be tuned far off-resonance by another, independent experimental knob, the external homogenous magnetic field. The results are summarized in Fig.12: We find very good agreement between the exact and the approximate model, with a negligibly small error  $\operatorname{Tr}\left[\rho\left|2\right\rangle\left\langle 2\right|\right] \sim \mathcal{O}\left(10^{-5}\right)$ . This justifies the approximations made above and shows that (in the regime of interest) the system can simply be described by Eq.(G15).

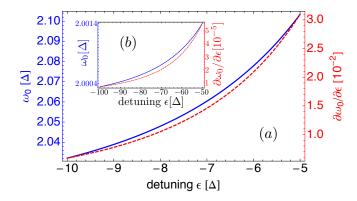


Figure 13: (color online). Transition frequency  $\omega_0$  (blue solid) and its sensitivity against charge noise induced fluctuations in  $\epsilon$  for intermediate (a) and large (b) negative detuning; for large negative detuning  $\omega_0 \approx 2\Delta$ , and the sensitivity  $\partial \omega_0 / \partial \epsilon$ practically vanishes leaving nuclear noise as the dominant dephasing process. By occasional refocusing of the spin states, this regime can be used for long-term storage of quantum information [69]. Other numerical parameters:  $t_c = 5\Delta$ .

## Noise Sources for the DQD-based System

Charge noise.—In a DQD device background charge fluctuations and noise in the gate voltages may cause undesired dephasing processes. In a recent experimental study [91], voltage fluctuations in the intedot detuning parameter  $\epsilon$  have been identified as the main source of charge noise in a singlet-triplet qubit. Charge noise can be treated by introducing a Gaussian distribution in  $\epsilon$ , with a variance  $\sigma_{\epsilon}$ ; typically  $\sigma_{\epsilon} \approx (1-3) \,\mu \text{eV}$  [89]. The qubit's transition frequency  $\omega_0$ , however, turns out to be rather insensitive to fluctuations in  $\epsilon$ , with a (tunable) sensitivity of approximately  $\partial \omega_0 / \partial \epsilon \lesssim 10^{-2}$ ; see Fig.13. In agreement with experimental results presented in Ref.[91], we find  $\partial \omega_0 / \partial \epsilon \sim \omega_0$ , indicating  $\omega_0$  to be an exponential function of  $\epsilon$ . At very negative detuning  $\epsilon$ , dephasing due to charge noise is practically absent, and  $T_2^{\star}$  will be limited by nuclear noise [91]. Fluctuations in the tunneling amplitude  $t_c$  can be treated along the lines: we find  $\omega_0$  to be similarly insensitive to noise in  $t_c$ ,  $\partial \omega_0 / \partial t_c \approx 10^{-2}$ .

Nuclear noise: Spin echo.—The electronic qubit introduced above has been defined for a fixed set of parameters  $(t_c, \epsilon, \Delta)$ ; compare Eq.(G6). Now, let us consider the effect of deviations from this fixed parameters,  $H_0 \to H_0 + \delta H$ , where  $\delta H$  can be decomposed as  $\delta H = \delta H_{\rm el} + \delta H_{\rm nuc}$  with

$$\delta H_{\rm el} = \frac{\delta t_c}{2} \left( |S_{02}\rangle \langle S_{11}| + \text{h.c.} \right) - \delta \epsilon |S_{02}\rangle \langle S_{02}|(G16)\rangle$$

$$\delta H_{\rm nuc} = -\delta \Delta \left( |T_0\rangle \left\langle S_{11} | + \text{h.c.} \right\rangle, \qquad (G17)$$

where  $\delta t_c$  and  $\delta \epsilon$  can be tuned electrostatically and basically in-situ. In most practical situations this does not hold for  $\delta \Delta$ : The primary source of decoherence in this system has been found to come from (slow) fluctuations in the Overhauser field generated by the nuclear spins [65, 66, 68]. In our model, this can directly be identified with a random, slowly time-dependent parameter  $\delta \Delta = \delta \Delta(t)$ . In the relevant subspace  $\{|0\rangle, |1\rangle\}, \, \delta H_{\rm nuc}$ is given by  $\delta H_{\rm nuc} = -\delta \Delta \sum_{k,l} \alpha_k \beta_l \, [|k\rangle \, \langle l| + {\rm h.c.}]$ . Typically,  $\delta \Delta \approx 0.1 \mu {\rm eV} \ll \omega_c$  is fulfilled, such that we can apply a RWA yielding  $\delta H_{\rm nuc} \approx -2\delta \Delta \sum_l \alpha_l \beta_l \, |l\rangle \, \langle l|$ ; physically,  $\delta H_{\rm nuc}$  is too weak to drive transitions between the electronic levels  $|0\rangle$  and  $|1\rangle$  which are energetically separated by  $\omega_0 \approx \omega_c$ . Then, in the spin basis used in Eq.(G11), we find

$$\delta H_{\rm nuc} = \delta \left( t \right) S^z, \tag{G18}$$

where the gradient noise is given by  $\delta(t) = 2\delta\Delta(t) (\alpha_0\beta_0 - \alpha_1\beta_1)$ . For  $(t_c, \epsilon, \Delta) \approx (5, -7, 1) \mu eV$ ,  $\alpha_0\beta_0 - \alpha_1\beta_1 \approx 0.9$ . Therefore, when also accounting for nuclear noise as described by Eq.(G18), the full model [compare Eq.(G11)] reads

$$\tilde{H}_{\rm DQD} = \left[\bar{\delta} + \delta\left(t\right)\right]S^{z} + g_{\rm QD}\left[S^{+}a + S^{-}a^{\dagger}\right].$$
 (G19)

Since the nuclear spins evolve on timescales much longer than all other relevant timescales  $\sim \kappa^{-1}, g^{-1}$  [64], the Overhauser noise term can be approximated as quasistatic, that is  $\delta(t) = \delta$ . As experimentally demonstrated in Ref.[66], the slow (nuclear) noise term  $\sim \delta(t) S^z$  can be neutralized by Hahn-echo techniques. Here, the dephasing time of the electron spin qubit was extended by more than three orders of magnitude from  $T_2^* \approx (10 - 100)$  ns to  $T_2 = 276 \mu$ s.

In the following, assuming nominal resonance  $\bar{\delta} = 0$ , we detail a sequence of Hahn-echo pulses that cancels the undesired noise term and restores the pure, resonant Jaynes-Cummings dynamics: We consider four short time intervals of length  $\tau$ , for which the unitary evolution is approximately given by  $U_i \approx 1 - iH_i\tau$ , interspersed by three  $\pi$ -pulses. First, we let the system evolve with  $H_1 = \delta S^z + g_{\text{QD}} \left[ S^+ a + S^- a^\dagger \right]$ , then we apply a  $\pi$ -pulse along  $\hat{x} \left( S^z \to -S^z, S^x \to S^x, S^y \to -S^y \right)$  such that  $S^{\pm} \to S^{\mp}$  and the system evolves in the second time interval with  $H_2 = -\delta S^z +$  $g_{\rm QD} \left[ S^- a + S^+ a^{\dagger} \right]$ . Next, we apply a  $\pi$ -pulse along  $\hat{z}$  $(\widetilde{S^z} \to S^z, S^x \to -S^x, S^y \to -S^y)$  such that  $S^{\pm} \to -S^{\pm}$ leading to  $H_3 = -\delta S^z - g_{\rm QD} [S^-a + S^+a^\dagger]$ . Finally, a  $\pi$ -pulse along  $\hat{y} (S^z \to -S^z, S^x \to -S^x, S^y \to S^y)$  is applied such that  $S^{\pm} \to -S^{\mp}$  giving  $H_4 = \delta S^z +$  $g_{\rm QD} \left[ S^+ a + S^- a^\dagger \right]$ . In summary, the system evolves over a time interval of  $4\tau$  according to  $U_{\rm eff} = U_4 U_3 U_2 U_1 \approx$  $1 - i\tau \sum_{i} H_{i} = 1 - iH_{\text{eff}} 4\tau$  with the effective Hamiltonian

$$H_{\text{eff}} = \frac{g_{\text{QD}}}{2} \left[ S^+ a + S^- a^\dagger \right]. \tag{G20}$$

Thus, in order to cancel the noise term, the effective single-phonon coupling strength is only lowered by a factor of 1/2.

### **Different Spin-Resonator Coupling**

In Appendix G, we have shown how to realize the prototypical Jaynes-Cummings Hamiltonian for SAW phonons interacting with a DQD; see Eq.(G11). Alternatively, if one does not absorb the gradient  $\Delta$  into the definition of the qubit basis, one can identify the logical subspace with the electronic states  $|T_0\rangle$  and  $|S\rangle$ , where  $|S\rangle$  is one of the two hybridized singlets (while the other one  $|S'\rangle$  is far detuned and neglected) [65, 66, 68, 91]. Here, the electronic Hamiltonian reads  $H_0 = -J(\epsilon) |S\rangle \langle S| - \tilde{\Delta} (|T_0\rangle \langle S| + \text{h.c.})$ , where  $\tilde{\Delta} = \langle S_{11} | S \rangle \Delta$  and  $J(\epsilon)$  describes the exchange interaction. In this regime, the spin-resonator interaction takes on a form that is well known from other (localized) implementations of mechanical resonators [9], namely

$$H_{\rm int} = g_{\rm qd} \left( a + a^{\dagger} \right) \otimes \left| S \right\rangle \left\langle S \right|, \qquad (G21)$$

which can be viewed as a phonon-state dependent force, leading to a shift of the qubit's transition frequency depending on the position  $\hat{x} = (a + a^{\dagger})/\sqrt{2}$ . Here, the single-phonon Rabi frequency is  $g_{\rm qd} = \kappa_S^2 \eta_{\rm geo} e \phi_0 \mathcal{F}(kd)$ , with  $\kappa_S = \langle S_{02} | S \rangle$ . Based on the coupling of Eq.(G21), one can envisage a variety of experiments known from quantum optics: For example, in the limit of vanishing gradient  $\Delta = 0$ , the  $\hat{x}$  quadrature of the phonon mode could serve as a quantum nondemolition variable, as it is a integral of motion of the coupled system of phonon mode and electronic meter.

## Appendix H: Generalized Definition of the Cooperativity Parameter

In this Appendix we provide a generalized discussion of the cooperativity parameter C which in particular accounts for losses of the cavity mode other than leakage through the non-perfect mirrors. Furthermore, we derive a simple, analytical estimate for the state transfer fidelity  $\mathcal{F}$  in terms of the parameter C and undesired phonon losses with a rate  $\sim \kappa_{\rm bd}$ .

We consider a single qubit  $\{|0\rangle, |1\rangle\}$  coupled to a cavity mode. The system is described by the Master equation

$$\dot{\varrho} = \underbrace{\left(\kappa_{\rm gd} + \kappa_{\rm bd}\right) \mathcal{D}\left[a\right] \varrho - i\left[H_{\rm JC}, \varrho\right] + \Gamma_{\rm deph} \mathcal{D}\left[\left|1\right\rangle \left\langle 1\right|\right] \varrho}_{\mathcal{V}_{\varrho}},\tag{H1}$$

where  $\mathcal{D}[a] \varrho = a \varrho a^{\dagger} - \frac{1}{2} \{a^{\dagger}a, \varrho\}$ . The first term describes decay of the cavity mode. The corresponding decay rate can be decomposed into desired (leakage through the mirrors) and undesired (bulk mode conversion etc.) contributions, labeled as  $\kappa_{\rm gd}$  and  $\kappa_{\rm bd}$ , respectively. Thus, we write  $\kappa = \kappa_{\rm gd} + \kappa_{\rm bd}$ . The second term with (on resonance)  $H_{\rm JC} = g \left(S^+a + S^-a^{\dagger}\right)$  refers to the coherent interaction between qubit and cavity mode, while the last term describes pure dephasing of the qubit with a rate  $\Gamma_{\rm deph}$ .

In the bad cavity limit (where  $\kappa \gg g$ ,  $\Gamma_{deph}$ ), one can adiabatically eliminate the cavity mode by projecting the system onto the cavity vacuum,  $\mathcal{P}\varrho = \operatorname{Tr}_{cav} [\varrho] \otimes \rho_{cav}^{ss} = \rho \otimes |\operatorname{vac}\rangle \langle \operatorname{vac}|$ . Standard techniques (perturbation theory up to second order in  $\mathcal{V}$ , compare Ref.[92]) then yield the effective Master equation for the qubit's density matrix  $\rho = \operatorname{Tr}_{cav} [\mathcal{P}\varrho]$  only,

$$\dot{\rho} = \tilde{\kappa} \mathcal{D} \left[ S^{-} \right] \rho + \Gamma_{\text{deph}} \mathcal{D} \left[ \left| 1 \right\rangle \left\langle 1 \right| \right] \rho, \tag{H2}$$

with the effective decay rate  $\tilde{\kappa} = 4g^2/\kappa$ .

For comparison, the same procedure in standard cavity QED, where  $\kappa = \kappa_{\rm gd}$  and  $\Gamma_{\rm deph} \mathcal{D}[|1\rangle \langle 1|] \rho \to \gamma \mathcal{D}[S^{-}] \rho$ , yields the effective Master equation for the atom only,  $\dot{\rho} = \tilde{\kappa} \mathcal{D}[S^{-}]\rho + \gamma \mathcal{D}[S^{-}]\rho$ . Therefore, the atom decays with an effective spontaneous emission rate  $\gamma_{tot}$  enhanced by the Purcell factor,  $\gamma_{\text{tot}} = \gamma + \tilde{\kappa} = (1 + 4g^2/\kappa\gamma)\gamma$ . Comparing good ~  $\tilde{\kappa}$  to bad ~  $\gamma$  decay channels, here one defines the cooperativity parameter in a straightforward way as  $C_{\text{atom}} = g^2 / \kappa \gamma$ . This is readily read as the cavity-to-free-space scattering ratio, since the effective rate at which an excited atom emits an excitation into the cavity is given by  $\tilde{\kappa} \sim g^2/\kappa$ . For  $C_{\text{atom}} > 1$ , the atom is then more likely to decay into the cavity mode rather than into another mode outside the cavity. In cavity QED, large cooperativity  $C_{\rm atom} \gg 1$  has allowed for a number of key experimental demonstrations such as an enhancement of spontaneous emission [93], photon blockade [94] and vacuum-induced transparency [95].

The Master equation given in Eq.(H2) describes a twolevel system subject to purely dissipative dynamics. The dynamics can be fully described in terms of a set of three simple rate equations for the populations  $p_k = \langle k | \rho | k \rangle$ (k = 0, 1) and coherence  $\rho_{10} = \langle 1 | \rho | 0 \rangle$ , summarized as  $\vec{p} = (p_1, p_0, \rho_{10})$ ,

$$\frac{d}{dt}\vec{p} = \begin{pmatrix} -\tilde{\kappa} & 0 & 0\\ +\tilde{\kappa} & 0 & 0\\ 0 & 0 & -\gamma_{\rm eff}/2 \end{pmatrix} \vec{p},$$
 (H3)

where  $\gamma_{\text{eff}} = (\tilde{\kappa} + \Gamma_{\text{deph}})$ . This allows for a simple analytical solution: For example, for a system initially in the excited state  $\rho(t=0) = |1\rangle \langle 1|$  it reads  $p_1(t) = \exp[-\tilde{\kappa}t]$ ,  $p_0 = 1 - \exp[-\tilde{\kappa}t]$  and  $\rho_{10}(t) = 0$ .

Here, we aim for a theoretical description that singles out the desired trajectories, where phonon emission through the mirrors happens first, from all others. To do so, we rewrite Eq.(H2) as

$$\dot{\rho} = -iH\rho + i\rho H^{\dagger} + \mathcal{J}_{\rm gd}\rho + \mathcal{J}_{\rm bd}\rho, \qquad ({\rm H4})$$

where we have defined an effective (non-hermitian) Hamiltonian H and jump operators according to

$$H = -\frac{i}{2}\gamma_{\text{eff}} \left| 1 \right\rangle \left\langle 1 \right| = -\frac{i}{2} \left( \tilde{\kappa} + \Gamma_{\text{deph}} \right) \left| 1 \right\rangle \left\langle 1 \right|, (\text{H5})$$

$$\mathcal{J}_{\rm gd}\rho = \tilde{\kappa}_{\rm gd}S^-\rho S^+, \tag{H6}$$

$$\mathcal{J}_{\rm bd}\rho = \tilde{\kappa}_{\rm bd}S^{-}\rho S^{+} + \Gamma_{\rm deph} \left|1\right\rangle \left\langle 1\right|\rho \left|1\right\rangle \left\langle 1\right|. \qquad ({\rm H7})$$

Here, we have decomposed the effective decay rate  $\tilde{\kappa}$  as

$$\tilde{\kappa} = \tilde{\kappa}_{\rm gd} + \tilde{\kappa}_{\rm bd} = \frac{4g^2}{\kappa^2} \kappa_{\rm gd} + \frac{4g^2}{\kappa^2} \kappa_{\rm bd}.$$
 (H8)

Formally solving Eq.(H4) gives

$$\rho(t) = \mathcal{U}(t)\rho(0) + \int_0^t d\tau \mathcal{U}(t-\tau)\mathcal{J}\rho(\tau), \qquad (\mathrm{H9})$$

with the total jump operator  $\mathcal{J}\rho = \mathcal{J}_{gd}\rho + \mathcal{J}_{bd}\rho$  and

$$\mathcal{U}(t)\,\rho = e^{-iHt}\rho e^{iH^{\dagger}t} \tag{H10}$$

The exact solution given in Eq.(H9) can be iterated, giving an illustrative expansion in terms of the jumps  $\mathcal{J}$ . It reads

$$\rho(t) = \mathcal{U}(t) \rho(0) + \int_0^t d\tau_1 \mathcal{U}(t - \tau_1) \mathcal{J}\mathcal{U}(\tau_1) \rho(0) + \int_0^t d\tau_2 \int_0^{\tau_2} d\tau_1 \mathcal{U}(t - \tau_2) \mathcal{J}\mathcal{U}(\tau_2 - \tau_1) \times \mathcal{J}\mathcal{U}(\tau_1) \rho(0) + \dots$$

Here, the *n*-th order term comprises n jumps  $\mathcal{J}$  with free evolution  $\mathcal{U}$  between the jumps. Now, we can single out the desired events where the first quantum jump is governed by  $\mathcal{J}_{gd}$ . This leads to the definition

$$\rho(t) = \mathcal{U}(t)\rho(0) + \rho_{\rm gd}(t) + \rho_{\rm bd}(t), \qquad (\text{H11})$$

where  $\rho_{\rm gd}(t)$  subsumes all desired trajectories

$$\rho_{\rm gd}(t) = \int_0^t d\tau_1 \mathcal{U}(t-\tau_1) \mathcal{J}_{\rm gd} \mathcal{U}(\tau_1) \rho(0) \qquad (\text{H12})$$
$$+ \int_0^t d\tau_2 \int_0^{\tau_2} d\tau_1 \mathcal{U}(t-\tau_2) \mathcal{J} \mathcal{U}(\tau_2-\tau_1) \times$$
$$\mathcal{J}_{\rm gd} \mathcal{U}(\tau_1) \rho(0) + \dots$$

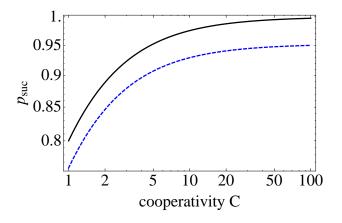


Figure 14: (color online). Success probability  $p_{\rm suc}$  for a qubit excitation to leak through the mirror, as a function of the cooperativity C for  $\varepsilon = \kappa_{\rm bd}/\kappa_{\rm gd} = 0$  (black solid) and  $\varepsilon = 5\%$  (blue dashed).

We focus on a qubit, initially in the excited state, i.e.,  $\rho(0) = |1\rangle \langle 1|$ . Using the relations  $\mathcal{U}(\tau_1) \rho(0) = e^{-\gamma_{\text{eff}} \tau_1} |1\rangle \langle 1|$ ,  $\mathcal{J}_{\text{gd}} \mathcal{U}(\tau_1) \rho(0) = \tilde{\kappa}_{\text{gd}} e^{-\gamma_{\text{eff}} \tau_1} |0\rangle \langle 0|$  and

$$\mathcal{J}_{\mathrm{gd}}\mathcal{U}\left(\tau_{2}-\tau_{1}\right)\mathcal{J}_{\mathrm{gd}}\mathcal{U}\left(\tau_{1}\right)\rho\left(0\right) = 0, \qquad (\mathrm{H13})$$

$$\mathcal{J}_{\rm bd}\mathcal{U}\left(\tau_2 - \tau_1\right)\mathcal{J}_{\rm gd}\mathcal{U}\left(\tau_1\right)\rho\left(0\right) = 0,\qquad({\rm H}14)$$

the qubit's density matrix evaluates (to all orders in  $\mathcal{J}$ ) to

$$\rho(t) = e^{-\gamma_{\text{eff}}t} \left|1\right\rangle \left\langle 1\right| + \rho_{\text{gd}}\left(t\right) + \rho_{\text{bd}}\left(t\right), \quad (\text{H15})$$

$$\rho_{\rm gd}\left(t\right) = \frac{\kappa_{\rm gd}}{\gamma_{\rm eff}} \left(1 - e^{-\gamma_{\rm eff}t}\right) \left|0\right\rangle \left\langle0\right|. \tag{H16}$$

In the long-time limit  $t \to \infty$ , the system reaches the steady state,  $\rho(t \to \infty) = \rho_{\rm gd} + \rho_{\rm bd}$ , where  $\rho_{\rm gd} = \frac{\tilde{\kappa}_{\rm gd}}{\gamma_{\rm eff}} |0\rangle \langle 0|$ . The associated success probability  $p_{\rm suc} = \text{Tr} [\rho_{\rm gd}]$  for faithful decay through the mirrors is then

$$p_{\rm suc} = \frac{\tilde{\kappa}_{\rm gd}}{\tilde{\kappa}_{\rm gd} + \tilde{\kappa}_{\rm bd} + \Gamma_{\rm deph}} = \frac{1}{\frac{\kappa}{\kappa_{\rm gd}} + \frac{1}{4} \frac{\kappa^2 \Gamma_{\rm deph}}{g^2 \kappa_{\rm gd}}}, \quad (\text{H17})$$

which is a simple branching ratio comparing the strength of the desired decay channel  $\sim \tilde{\kappa}_{\rm gd}$  to the undesired ones  $\sim \tilde{\kappa}_{\rm bd} + \Gamma_{\rm deph}$ . In the limit where  $\kappa_{\rm bd} = 0$ , i.e.,  $\kappa = \kappa_{\rm gd}$ , the expression for  $p_{\rm suc}$  simplifies to

$$p_{\rm suc} = \frac{1}{1 + \frac{1}{4}\frac{1}{C}} \xrightarrow{C \gg 1} 1, \tag{H18}$$

with the usual definition found in the literature,  $C = g^2/(\kappa\Gamma_{\text{deph}}) = g^2T_2/\kappa$ ; here,  $\kappa = \omega_c/Q_{\text{eff}} = (\bar{n}_{\text{th}} + 1)\omega_c/Q$  is understood to account for thermal occupation of the environment  $\bar{n}_{\text{th}}$  in terms of a decreased mechanical quality factor (compare for example Refs.[10, 60]).

It is instructive to rewrite the general expression for  $p_{\rm suc}$  given in Eq.(H17) as

$$p_{\rm suc} = \frac{1}{\left(1+\varepsilon\right)\left[1+\frac{1}{4C}\right]}.\tag{H19}$$

with  $\varepsilon = \kappa_{\rm bd}/\kappa_{\rm gd}$ . Based on this definition, it is evident that two conditions need to be satisfied in order to reach  $p_{\rm suc} \to 1$  in the regime where  $\kappa_{\rm bd} > 0$ : (i) a low undesired loss rate,  $\varepsilon = \kappa_{\rm bd}/\kappa_{\rm gd} \ll 1$ , and (ii) high cooperativity,  $C \equiv \frac{g^2}{\kappa\Gamma_{\rm deph}} = \frac{g^2 T_2}{\kappa} \gg 1$ , with  $\kappa = \kappa_{\rm gd} + \kappa_{\rm bd}$ . For an illustration, compare Fig.14. This shows, that the usual definition and interpretation of the cooperativity C holds, provided that  $\varepsilon \ll 1$  is fulfilled. In order to quantify the cooperativity C for SAW cavity modes both in the  $\sim$  MHz ( $\bar{n}_{\rm th} \gg 1$ ) and the  $\sim$  GHz ( $\bar{n}_{\rm th} \ll 1$ ) regime, in the main text we take a (conservative) estimate as  $C \equiv g^2 T_2 Q / [\omega_c (\bar{n}_{\rm th} + 1)]$ . For artificial atoms (quantum dots, superconducting qubits, NV-centers, ...) with resonant frequencies  $\sim$  GHz, at cryostatic temperatures this definition reduces to  $C \approx g^2 T_2 / \kappa$  as discussed above, whereas for a trapped ion with  $\omega_t/2\pi \approx \omega_c/2\pi \sim$  MHz

it correctly gives  $C \approx g^2 T_2 Q / (\omega_c \bar{n}_{\rm th})$  with a decreased effective quality factor  $Q_{\rm eff} = Q / \bar{n}_{\rm th}$  [10, 96, 97].

Fidelity estimate.—For small errors, the expression given in Eq.(H19) can be approximated as  $p_{\rm suc} \approx 1 - \varepsilon - 1/(4C)$ . Since the absorption process is just the time-reversed copy of the emission process in the state transfer protocol for two nodes, we can estimate the state transfer fidelity as  $\mathcal{F} \geq p_{\rm suc} \times p_{\rm suc}$ . For small infidelities, we then find

$$\mathcal{F} \gtrsim 1 - 2\varepsilon - \frac{1}{2C},$$
 (H20)

where the individual errors arise from intrinsic phonon losses ~  $\varepsilon$  and qubit dephasing ~  $C^{-1} \sim T_2^{-1}$ , respectively. This simple analytical estimate agrees well with numerical results presented in Ref. [61], where (except for noise sources that are irrelevant for our problem)  $\mathcal{F} \approx 1 - (2/3)\varepsilon/(1+\varepsilon) - \mathcal{C}C^{-1}$  with a numerical coefficient  $\mathcal{C} = \mathcal{O}(1)$  depending on the specific pulse sequence. Since  $\varepsilon \ll 1$ , this relation can be simplified to  $\mathcal{F} \approx 1 - (2/3)\varepsilon - \mathcal{C}C^{-1}$ . For the state transfer of the coherent superposition  $|\psi\rangle = (|0\rangle - |1\rangle)/\sqrt{2}$  as described in detail in Appendix J, we have explicitly verified the linear scaling  $\sim \varepsilon$  and find numerically  $\sim 1/2\varepsilon$  for intrinsic phonon losses [compare also Fig.4 in the main text, where  $\mathcal{F} \approx 95\%$  for  $\varepsilon \approx 10\%$  and  $\sigma_{\rm nuc} = 0$  and take  $\sim \varepsilon$  as a simple estimate in Eq.(8). Using experimentally achievable parameters  $\varepsilon \approx 5\%$  and  $C \approx 30$ , we can then estimate  $\mathcal{F} \approx 90\%$ .

### Appendix I: Effects due to the Structure Defining the Quantum Dots

In our analysis of charge and spin qubits defined in quantum dots, we have neglected any potential effects arising due to the structure defining the quantum dots, that is (i) the heterostructure for the 2DEG and (ii) the metallic top gates for confinement of single electrons. In this Appendix, we give several arguments corroborating this approximate treatment, showing that the QD structure does not negatively influence the cavity nor the coupling between qubit and cavity.

Heterostructure.—Following the arguments given in Ref.[25], the 2DEG is taken to be a thin conducting layer a distance d away from the surface of a homogeneous  $Al_xGa_{1-x}As$  crystal with typically  $x \approx 30\%$ . This treatment is approximately correct since the relevant material properties (elastic constants, densities and dielectric constants) of  $Al_xGa_{1-x}As$  and GaAs are very similar [25]. The mode-functions and speed of sound are largely defined by the elastic constants [25] which are roughly the same for both  $Al_xGa_{1-x}As$  and pure GaAs; for example, the speed of the Rayleigh SAW for  $Al_{0.3}Ga_{0.7}As$ is  $v_s \approx 3010$ m/s which differs from that of pure GaAs by only 5% [25]. Moreover, the numerical values for the material-dependent parameter H entering the amplitude of the mechanical zero-point motion  $U_0$  according to Eq.(C9) differ by 2% only [25]; accordingly, the estimate for our key figure of merit  $U_0$  should be rather accurate. Also, the piezo-electric coupling constants are rather similar, with  $e_{14} \approx 0.15$ C/m<sup>2</sup> for pure GaAs and  $e_{14} \approx 0.145$ C/m<sup>2</sup> for Al<sub>0.3</sub>Ga<sub>0.7</sub>As [24, 25] yielding an accurate estimate for  $\phi_0$  and  $\xi_0$ , respectively. Lastly, the heterostructure is not expected to severely affect the Q-factor, since very high Q-values reaching  $Q > 10^4$ have been observed in previous SAW experiments on AlN/diamond heterostructures [53, 54], where the differences in material properties are considerably larger than for the heterostructure making up the 2DEG.

Top gates.—For the following reasons, we have disregarded effects due to the presence of the metallic top gates: (i) In Ref.[27], a closed form analytic solution for the piezoelectric potential  $\phi(\mathbf{x}, t)$  accompanying a SAW on the surface of a  $GaAs/Al_xGa_{1-x}As$  in the presence of a narrow metal gate has been obtained. In particular, it is shown that  $\phi(\mathbf{x},t)$  is screened *right* below the gate, but remains practically unchanged with respect to the ungated case outside of the edges of the gate. Since the QD electrons are confined to regions outside of the metallic gates, they experience the piezoelectric potential as calculated for the ungated case (see Appendix **B** for details); therefore, our estimates—where this screening effect has been neglected—remain approximately valid. (ii) In Ref. [46], the coupling of a traveling SAW to electrons confined in a DQD has been experimentally studied. Here, in very good agreement to the experimental results, the potential felt by the QD electrons has been taken as  $V_{\rm pe} \sim \sin(kl)$  (where l is the lithographic distance between the dots) confirming the sine-like mode profile as used in our estimates. Moreover, with l = 220 nm and  $\lambda = 1.4 \mu$ m the parameters used in this experiment perfectly match the ones used in our estimates. Intuitively (in the spirit of the standard electric dipole approximation in quantum optics), since  $\lambda \gg l$ , the SAW mode cannot resolve the dot structure and thus remains largely unaffected. (iii) In Ref.[16], single phonon SAW pulses have been detected via a single electron transistor (SET) directly deposited on the GaAs substrate with time-resolved measurements clearly identifying the coupling as piezo-electric. Similarly to a QD, the SET is defined by metallic gates. Here, a relation between vertical surface displacement and surface charge induced on the SET is theoretically derived. Using standard tabulated parameter values for GaAs and neglecting any effects due to the presence of the metallic gates, very good agreement with the experimental results is achieved. In particular, based on the results given in Ref.[16], a straightforward estimate gives  $U_0 \approx 30$  am for the rather large cavity with  $A \approx 10^6 \mu \text{m}^2$ , whereas Eq.(4) yields a smaller, conservative estimate  $U_0 \approx 2$ am, due to the averaging over the quantization area A. (iv) The Q-factor of the cavity is not expected to be severely affected by the presence of the metallic gates since metallic Al cladding layers have been used on a GaAs substrate to show basically dissipation-free SAW propagation over millimeter distances [38, 39]. (v) Finally, there is a large body of previous theoretical works on electronphonon coupling in gate-defined QDs (see for example Refs.[24, 87, 88, 98]) where any effects due to the structure defining the QDs have been neglected as well. As a matter of fact, our description for the electron-phonon coupling emerges directly from these previous treatments in the limit where the continuum of phonon modes is replaced by a single relevant SAW cavity mode (similar to cavity QED, other bulk modes are still present and contribute to the decoherence of the qubit on a timescale  $T_2$ ). For example, the piezoelectric electron-phonon interaction is given in Ref.[98] as

$$H_{\text{GaAs}} = \beta \sum_{k,\mu} \sqrt{\frac{\hbar}{2\rho V v_{\mu} k}} \mathcal{M}_k \left[ a_{k,\mu} + a_{-k,\mu}^{\dagger} \right], \quad (I1)$$

where  $a_{k,\mu}^{\dagger}$  creates an acoustic phonon with wave vector k and polarization  $\mu$  and  $\mathcal{M}_k$  refers to the matrix element for electron-phonon coupling; for free bulk modes,  $\mathcal{M}_k = \sum_{i,j} \sum_{\sigma} \langle i | \exp[i\mathbf{kr}] | j \rangle d_{i\sigma}^{\dagger} d_{j\sigma}$ . In agreement with our notation, the coupling constant is  $\beta = ee_{14}/\epsilon$  and the square-root factor can be identified with  $U_0$ . Replacing the sum by a single-relevant cavity mode a, we recover the Hamiltonian describing the cavity-qubit coupling with  $g \sim \beta U_0 = e\phi_0$ ; compare Eq.(F1).

#### Appendix J: State Transfer Protocol

In this Appendix, we provide further details on the numerical simulation of the state transfer protocol as described by Eqs.(9) and (10), in the presence of Markovian noise. In line with previous theoretical studies [97], we show that the simple approximate Markovian noise treatment results in a pessimistic estimate for the noise transfer fidelity  $\mathcal{F}$ .

We first provide results of the full time-dependent numerical simulation of the cascaded Master equation given in Eqs.(9) and (10), including an exponential loss of coherence for  $\Gamma_{\text{deph}} > 0$ ; see Fig.15. In contrast to the non-Markovian noise model discussed in the main text, the qubits are assumed to be on resonance throughout the evolution, that is  $\delta_i = 0$  (i = 1, 2), but experience undesired noise as described by

$$\mathcal{L}_{\text{noise}}\rho = 2\kappa_{\text{bd}} \sum_{i=1,2} \mathcal{D}\left[a_i\right]\rho + \Gamma_{\text{deph}} \sum_{i=1,2} \mathcal{D}\left[S_i^z\right]\rho. \quad (J1)$$

Here, the second term refers to a standard Markovian

pure dephasing term that leads to an exponential loss of coherence ~ exp  $(-\Gamma_{\text{deph}}t/2)$ . As a reference we also show the results for the ideal, noise-free scenario  $(\mathcal{L}_{\text{noise}} = 0)$ , where perfect state transfer is achieved [20]. The results of this type of time-dependent numerical simulations are then summarized in Fig.16. For optimized, but experimentally achievable parameters  $T_2^* \approx 3\mu s$ [68], and accordingly  $\Gamma_{\text{deph}}/\kappa_{\text{rd}} \approx 3\%$ , we then obtain

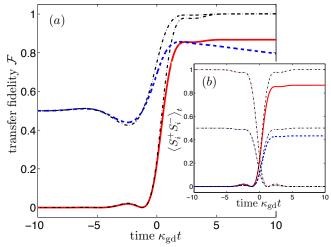


Figure 15: (color online). Numerical simulation of state transfer for two different initial states  $|1\rangle_1$  (red solid line) and  $(|0\rangle_1 - |1\rangle_1)/\sqrt{2}$  (blue dashed line) in the presence of Markovian noise. Black (dash-dotted) curves refer to the ideal, noise-free scenario ( $\mathcal{L}_{\text{noise}} = 0$ ) where perfect transfer is achieved, while colored curves take into account decoherence processes. (a) Transfer fidelity  $\mathcal{F}$ ; (b) Excited-state occupation  $\langle S_i^+ S_i^- \rangle_t$  for first and second qubit. Numerical parameters:  $g_1 (t \geq 0) = \kappa_{\text{gd}}, \kappa_{\text{bd}}/\kappa_{\text{gd}} = 5\%$  and  $\Gamma_{\text{deph}}/\kappa_{\text{gd}} = 5\%$ .

 $\mathcal{F} \approx 0.85$ , in the presence of realistic undesired phonon losses  $\kappa_{\rm bd}/\kappa_{\rm gd} = 5\%$ .

This shows that our non-Markovian noise model yields even higher state transfer fidelities than the Markovian noise model. Intuitively, this can be readily understood as follows: The simple Markovian noise model gives a coherence decay ~ exp  $(-t/T_2)$ , whereas our non-Markovian noise model yields ~ exp  $(-t^2/T_2^2)$ . Therefore, for Markovian noise one can estimate the dephasing induced error on the relevant timescale for state transfer ~  $\kappa^{-1}$  as ~  $\kappa^{-1}/T_2 \approx \Gamma_{\text{deph}}/\kappa \ll 1$ , whereas non-Markovian noise leads to a considerably smaller error ~  $(T_2^{-1}/\kappa)^2$ .

Systems, Nature 451, 664 (2008).

- R. Hanson and D. Awschalom, Coherent Manipulation of Single Spins in Semiconductors, Nature 453, 1043 (2008).
- [2] R. J. Schoelkopf and S. M. Girvin, Wiring up Quantum
- [3] A. Wallraff et al., Circuit Quantum Electrodynamics: Coherent Coupling of a Single Photon to a Cooper Pair Box, Nature 431, 162 (2004).

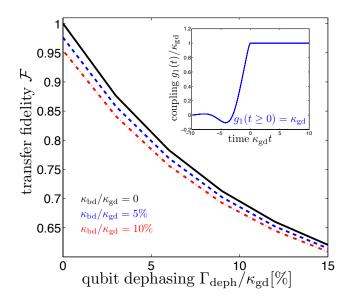


Figure 16: (color online). Quantum state-transfer protocol in the presence of Markovian noise. (a) State transfer fidelity  $\mathcal{F}$  for a coherent superposition  $|\psi\rangle = (|0\rangle - |1\rangle)/\sqrt{2}$ as a function of the qubit's dephasing rate  $\Gamma_{deph}$  for different values of intrinsic phonon losses  $\kappa_{bd}/\kappa_{gd} = 0$  (black solid),  $\kappa_{bd}/\kappa_{gd} = 5\%$  (blue dashed) and  $\kappa_{bd}/\kappa_{gd} = 10\%$  (red dashdotted). (b) Pulse shape  $g_1(t)$  for first node.

- [4] A. Blais, R.-S. Huang, A. Wallraff, S. M. Girvin, and R. J. Schoelkopf, *Cavity Quantum Electrodynamics for Superconducting Electrical Circuits: An Architecture for Quantum Computation*, Phys. Rev. A 69, 062320 (2004).
- [5] J. Majer et al., Coupling Superconducting Qubits via a Cavity Bus, Nature 449, 443 (2007).
- [6] M. A. Sillanpää, J. I. Park, and R. W. Simmonds, Coherent Quantum State Storage and Transfer between two Phase Qubits via a Resonant Cavity, Nature 449, 438 (2007).
- [7] A. D. O'Connell et al., Quantum Ground State and Single-Phonon Control of a Mechanical Resonator, Nature 464, 697 (2010).
- [8] A. N. Cleland and M. R. Geller, Superconducting Qubit Storage and Entanglement with Nanomechanical Resonators, Phys. Rev. Lett. 93, 070501 (2004).
- [9] P. Rabl, S. J. Kolkowitz, F. H. L. Koppens, J. G. E. Harris, P. Zoller, and M. D. Lukin, A Quantum Spin Transducer based on Nanoelectromechanical Resonator Arrays, Nat. Phys. 6, 602 (2010).
- [10] S. Kolkowitz, A. C. Bleszynski Jayich, Q. P. Unterreithmeier, S. D. Bennett, P. Rabl, J. G. E. Harris, and M. D. Lukin, *Coherent Sensing of a Mechanical Resonator with* a Single-Spin Qubit, Science **335**, 1603 (2012).
- [11] O.O. Soykal, R. Ruskov, and C. Tahan, Sound-Based Analogue of Cavity Quantum Electrodynamics in Silicon, Phys. Rev. Lett. 107, 235502 (2011).
- [12] R. Ruskov and C. Tahan, On-Chip Cavity Quantum Phonodynamics with an Acceptor Qubit in Silicon, Phys. Rev. B 88, 064308 (2013).
- [13] S. J. M. Habraken, K. Stannigel, M. D. Lukin, P. Zoller, and P. Rabl, Continuous Mode Cooling and Phonon Routers for Phononic Quantum Networks, New J. Phys.

14, 115004 (2012).

- [14] D. Morgan, Surface Acoustic Wave Filters (Academic Press, Boston, 2007).
- [15] S. Datta, Surface Acoustic Wave Devices (Prentice-Hall, Upper Saddle River, 1986).
- [16] M. V. Gustafsson, P. V. Santos, G. Johansson, and P. Delsing, Local Probing of Propagating Acoustic Waves in a Gigahertz Echo Chamber, Nat. Phys. 8, 338 (2012).
- [17] M. V. Gustafsson, T. Aref, A. F. Kockum, M. K. Ekström, G. Johansson, and P. Delsing, *Propagating Phonons Coupled to an Artificial Atom*, Science **346**, 207 (2014).
- [18] Depending on the particular physical implementation of the qubit, the Jaynes-Cummings type Hamiltonian given in Eq.(1) may emerge only as an effective description of a potentially driven, two- or multilevel system. However, for e.g. charge or spin qubits embedded in GaAs quantum dots it is a rather straightfoward way to describe the coherent dynamics of a single node.
- [19] The cooperativity parameter C compares the coherent single phonon coupling strength g with the geometric mean of the relevant incoherent processes, i.e., the qubit's decoherence rate and the cavity's effective linewidth; in direct analogy to cavity QED, it is a key figure of merit in our system as C > 1 marks the onset of coherent quantum effects in a coupled spin-oscillator system [10].
- [20] J. I. Cirac, P. Zoller, H. J. Kimble, and H. Mabuchi, Quantum State Transfer and Entanglement Distribution among Distant Nodes in a Quantum Network, Phys. Rev. Lett. 78, 3221 (1997).
- [21] A. El Habti, F. Bastien, E. Bigler, and T. Thorvaldsson, *High-Frequency Surface Acoustic Wave Devices at Very Low Temperature: Application to Loss Mechanisms Evaluation*, J. Acoust. Soc. Am. **100**, 272 (1996).
- [22] E. B. Magnusson, B. H. Williams, R. Manenti, M.-S. Nam, A. Nersisyan, M. J. Peterer, A. Ardavan, and P. J. Leek, Surface Acoustic Wave Devices on Bulk ZnO Crystals at Low Temperature, Appl. Phys. Lett. **106**, 063509 (2015).
- [23] R. Manenti, Surface Acoustic Wave Resonators for Quantum Information (Master thesis, University of Milano, 2013).
- [24] V. Kornich, C. Kloeffel, and D. Loss, *Phonon-Mediated Decay of Singlet-Triplet Qubits in Double Quantum Dots*, Phys. Rev. B 89, 085410 (2014).
- [25] S. H. Simon, Coupling of Surface Acoustic Waves to a Two-Dimensional Electron Gas, Phys. Rev. B 54, 13878 (1996).
- [26] D. Royer and E. Dieulesaint, *Elastic Waves in Solids I* (Springer, Berlin, 2000).
- [27] G. R. Aizin, G. Gumbs, M. Pepper, Screening of the Surface-Acoustic-Wave Potential by a Metal Gate and the Quantization of the Acoustoelectric Current in a Narrow Channel, Phys. Rev. B 58, 10589 (1998).
- [28] R. M. White, Surface Elastic Waves, Proceedings of the IEEE 58, 1238 (1970).
- [29] M. A. Stroscio, Y. M. Sirenko, S. Yu, and K. W. Kim, Acoustic Phonon Quantization in Buried Waveguides and Resonators, J. Phys. Condens. Matter 8, 2143 (1996).
- [30] The numerical values we obtain for  $\phi_0$  agree very well with material-dependent constants  $c_{\alpha} = |U_{\alpha}/\phi| \approx (0.1 - 1) \text{fm}/\mu \text{V}$  for  $(\alpha = x, z)$  tabulated in Refs.[14, 15].
- [31] M. Aspelmeyer, T. J. Kippenberg, and F. Marquardt, *Cavity Optomechanics* (Springer, Berlin, 2014).

- [32] J. P. Nowacki, Static and Dynamic Fields in Bodies with Piezoeffects or Polarization Gradient (Springer-Verlag, Berlin, 2006).
- [33] J. Cai, F. Jelezko, and M. B. Plenio, Hybrid Sensors based on Colour Centres in Diamond and Piezoactive Layers, Nature Commun. 5, 4065 (2014).
- [34] J.-X. Liu, D.-N. Fang, W.-Y. Wei, and X.-F. Zhao, Love Waves in Layered Piezoelectric/Piezomagnetic Structures, Journal of Sound and Vibration, **315**, 146 (2008).
- [35] Y. Pang, J.-X. Liu, Y.-S. Wang, and X.-F. Zhang, Propagation of Rayleigh-type Surface Waves in a Transversely Isotropic Piezoelectric Layer on a Piezomagnetic Half-Space, Journal of Applied Physics 103, 074901 (2008).
- [36] D. L. T. Bell and R. C. M. Li, Surface-Acoustic-Wave Resonators, Proc. of IEEE 64, 711 (1976).
- [37] R. C. M. Li, J. A. Alusow, and R. C. Williamson, Experimental Exploration of the Limits of Achievable Q of Grooved Surface-Wave Resonators, Ultrasonics Symposium Proceedings IEEE 75, 279 (1975).
- [38] M. M. de Lima and P. V. Santos, Modulation of Photonic Structures by Surface Acoustic Waves, Rep. Prog. Phys. 68, 1639 (2005).
- [39] M. M. de Lima, J. Camacho, W. Seidel, H. Kostial, P. V. Santos, *Intense Acoustic Beams for Photonic Modulation*, Proc. of SPIE **5450**, 118 (2004).
- [40] S. Büyükköse, B. Vratzov, D. Atac, J. van der Veen, P. V. Santos, and W. G. van der Wiel, Ultrahigh-Frequency Surface Acoustic Wave Transducers on ZnO/SiO<sub>2</sub>/Si using Nanoimprint Lithography, Nanotechnology 23, 315303 (2012).
- [41] B. Auld, Austic Fields and Waves in Solids II (Wiley, New York, 1973).
- [42] A.A. Oliner, Waveguides for Surface Waves, in A.A. Oliner (ed.), Acoustic Surface Waves, pp. 187–223 (Springer-Verlag, Berlin, 1978).
- [43] A. Frisk Kockum, P. Delsing, and G. Johansson, Designing Frequency-Dependent Relaxation Rates and Lamb Shifts for a Giant Artificial Atom, Phys. Rev. A 90, 013837 (2014).
- [44] M. Gao, Y.-x. Liu, and X.-B. Wang, Coupling Rydberg Atoms to Superconducting Qubits via Nanomechanical Resonator, Phys. Rev. A 83, 022309 (2011).
- [45] K. D. Petersson, J. R. Petta, H. Lu, and A. C. Gossard, Phys. Rev. Lett. 105, *Quantum Coherence in a One-Electron Semiconductor Charge Qubit*, 246804 (2010).
- [46] W. J. M. Naber, T. Fujisawa, H. W. Liu, and W. G. van der Wiel, Surface-Acoustic-Wave-Induced Transport in a Double Quantum Dot, Phys. Rev. Lett. 96, 136807 (2006).
- [47] D. I. Schuster et al., Resolving Photon Number States in a Superconducting Circuit, Nature 445, 515 (2007).
- [48] K. D. Petersson, L. W. McFaul, M. D. Schroer, M. Jung, J. M. Taylor, A. A. Houck, and J. R. Petta, *Circuit Quan*tum Electrodynamics with a Spin Qubit, Nature **490**, 380 (2012).
- [49] F. A. Zwanenburg, A. S. Dzurak, A. Morello, M. Y. Simmons, L. C. L. Hollenberg, G. Klimeck, S. Rogge, S. N. Coppersmith, and M. A. Eriksson, *Silicon Quantum Electronics*, Rev. Mod. Phys. 85, 961 (2013).
- [50] J. M. Raimond, M. Brune, and S. Haroche, Manipulating Quantum Entanglement with Atoms and Photons in a Cavity, Rev. Mod. Phys. 73, 565 (2001).
- [51] J. Labaziewicz, Y. Ge, P. Antohi, D. Leibrandt, K. R. Brown, and I. L. Chuang, *Suppression of Heating Rates*

in Cryogenic Surface-Electrode Ion Traps, Phys. Rev. Lett. **100**, 013001 (2008).

- [52] D. Kielpinski, D. Kafri, M. J. Woolley, G. J. Milburn, and J. M. Taylor, *Quantum Interface between an Electrical Circuit and a Single Atom*, Phys. Rev. Lett. **108**, 130504 (2012).
- [53] J. G. Rodriguez-Madrid, G. F. Iriarte, J. Pedros, O. A. Williams, D. Brink, and F. Calle, *Super-High-Frequency SAW Resonators on AlN/Diamond*, IEEE Electron Device Letters **33**, 495 (2012).
- [54] M. Benetti, D. Cannata, F. Di Pietrantonio, and E. Verona, Growth of AlN Piezoelectric Film on Diamond for High-Frequency Surface Acoustic Wave Devices, IEEE Transactions on Ultrasonics, Ferroelectrics, and Frequency Control 52, 1806 (2005).
- [55] J. M. Taylor, P. Cappellaro, L. Childress, L. Jiang, D. Budker, P. R. Hemmer, A. Yacoby, R. Walsworth, and M. D. Lukin, *High-Sensitivity Diamond Magnetometer with Nanoscale Resolution*, Nat. Phys. 4, 810 (2008).
- [56] L. Rondin, J.-P. Tetienne, T. Hingant, J.F. Roch, P. Malentinsky, and V. Jacques, *Magnetometry with Nitrogen-Vacancy Defects in Diamond*, Rep. Prog. Phys. 77, 056503 (2014).
- [57] Here, the constant background field generated by the piezo-magnetic material is absorbed into the definition of the external magnetic field  $\mathbf{B}_{ext}$ . For a typical situation as analyzed in Ref.[33] it is roughly a factor of five smaller than  $|\mathbf{B}_{ext}| \approx 0.235$ T.
- [58] Q. A. Turchette et al., Heating of Trapped Ions from the Quantum Ground State, Phys. Rev. A 61, 063418 (2000).
- [59] N. Bar-Gill, L. M. Pham, A. Jarmola, D. Budker, and R. L. Walsworth, *Solid-State Electronic Spin Coherence Time Approaching One Second*, Nature Commun. 4, 1743 (2013).
- [60] P. Ovartchaiyapong, K. W. Lee, B. A. Myers, and A. C. Bleszynski Jayich, *Dynamic Strain-Mediated Coupling of a Single Diamond Spin to a Mechanical Resonator*, Nature Commun. 5, 4429 (2014).
- [61] K. Stannigel, P. Rabl, A. S. Sorensen, P. Zoller, and M. D. Lukin, Optomechanical Transducers for Long-Distance Quantum Communication, Phys. Rev. Lett. 105, 220501 (2010).
- [62] This system is a particulary promising physical realization as it provides a relatively high cooperativity C even in the absence of spin-echo pulses, the spin-resonator Hamiltonian takes on the generic Jaynes-Cummings Hamiltonian Eq.(1) in a rather straight-forward way (Appendix G) [whereas Eq.(6) and (7) require further ingredients such as a MW drive (compare for example Ref.[13]) to effectively obtain Eq.(1)], and, outside of the statetransfer time window, it provides better control techniques such as spin-echo pulses than the simple chargequbit scenario.
- [63] C. Kloeffel and D. Loss, Prospects for Spin-Based Quantum Computing in Quantum Dots, Annu. Rev. Condens. Matter Phys. 4, 51 (2013).
- [64] E. A. Chekhovich, M. N. Makhonin, A. I. Tartakovskii, A. Yacoby, H. Bluhm, K. C. Nowack, and L. M. K. Vandersypen, *Nuclear Spin Effects in Semiconductor Quan*tum Dots, Nature Mat. **12**, 494 (2013).
- [65] S. Foletti, H. Bluhm, D. Mahalu, V. Umansky, and A. Yacoby, Universal Quantum Control of Two-Electron Spin Quantum Bits Using Dynamic Nuclear Polarization, Nat. Phys. 5, 903 (2009).

- [66] H. Bluhm, S. Foletti, I. Neder, M. Rudner, D. Mahalu, V. Umansky, and A. Yacoby, *Dephasing Time of GaAs Electron-Spin Qubits Coupled to a Nuclear Bath exceeding 200µs*, Nat. Phys. 7, 109 (2011).
- [67] I.T. Vink, K.C. Nowack, F.H.L. Koppens, J. Danon, Y.V. Nazarov, and L.M.K. Vandersypen, *Locking Electron Spins into Magnetic Resonance by Electron-Nuclear Feedback*, Nature Physics 5, 764 (2009).
- [68] M. D. Shulman, S. P. Harvey, J. M. Nichol, S. D. Bartlett, A. C. Doherty, V. Umansky, and A. Yacoby, *Suppressing Qubit Dephasing using Real-Time Hamiltonian Estima*tion, Nat. Commun. 5, 5156 (2014).
- [69] J. M. Taylor and M. D. Lukin, Cavity Quantum Electrodynamics with Semiconductor Double-Dot Molecules on a Chip, arXiv:cond-mat/0605144 (unpublished).
- [70] M. D. Shulman, O. E. Dial, S. P. Harvey, H. Bluhm, V. Umansky, and A. Yacoby, *Demonstration of Entanglement of Electrostatically Coupled Singlet-Triplet Qubits*, Science **336**, 202 (2012).
- [71] G. Burkard, and A. Imamoglu, Ultra-Long-Distance Interaction between Spin Qubits, Phys. Rev. B 74, 041307 (2006).
- [72] X. Hu, Y.-X. Liu, and F. Nori, Strong Coupling of a Spin Qubit to a Superconducting Stripline Cavity, PRB 86, 035314 (2012).
- [73] Note, however, that more elaborate optimization yields an optimal spot with an even larger coupling  $g \approx 0.3g_{\rm ch}$ [69].
- [74] C. W. Gardiner, Driving a Quantum System with the Output Field from another Driven Quantum System, Phys. Rev. Lett. 70, 2269 (1993).
- [75] H. J. Carmichael, Quantum Trajectory Theory for Cascaded Open Systems, Phys. Rev. Lett. 70, 2273 (1993).
- [76] In a perfect realization of the transfer scheme the system remains in a dark state throughout the evolution and no field is scattered from the second mirror. Therefore, the assumption of unidirectional propagation is not strictly needed; compare Ref.[20].
- [77] S. Massar and S. Popescu, Optimal Extraction of Information from Finite Quantum Ensembles, Phys. Rev. Lett. 74, 1259 (1995).
- [78] S. J. van Enk, J. I. Cirac, and P. Zoller, *Ideal Quantum Communication over Noisy Channels: A Quantum Optical Implementation*, Phys. Rev. Lett. **78**, 4293 (1997).
- [79] S. J. van Enk, J. I. Cirac, and P. Zoller, *Photonic Channels for Quantum Communication*, Science **279**, 205 (1998).
- [80] S. J. van Enk, H. J. Kimble, J. I. Cirac, and P. Zoller, *Quantum Communication with Dark Photons*, Phys. Rev. A 59, 2659 (1999).
- [81] M. Veldhorst et al., An Addressable Quantum Dot Qubit with Fault-Tolerant Control-Fidelity, Nature Nano. 9, 981 (2014).

- [82] R. Ruskov and C. Tahan, Catching the Quantum Sound Wave, Science 346, 165 (2014).
- [83] O.O. Soykal and C. Tahan, Toward Engineered Quantum Many-Body Phonon Systems, Phys. Rev. B 88, 134511 (2013).
- [84] R. Stoneley, The Propagation of Surface Elastic Waves in a Cubic Crystal, Proc. Soc. London, Ser. A 232, 447 (1955).
- [85] W. J. Tanski, *GHz SAW Resonators*, Ultrasonics Symp. Proc. IEEE **79**, 815 (1979).
- [86] J. P. Parekh and H. S. Tuan, Effect of Groove-Depth Variation on the Performance of Uniform SAW Grooved Reflector Arrays, Appl. Phys. Lett. 32, 787 (1978).
- [87] H. Bruus, K. Flensberg, and H. Smith, Magnetoconductivity of Quantum Wires with Elastic and Inelastic Scattering, Phys. Rev. B 48, 11144 (1993).
- [88] T. Brandes and B. Kramer, Spontaneous Emission of Phonons by Coupled Quantum Dots, Phys. Rev. Lett. 83, 3021 (1999).
- [89] S. Chesi, Y.-D. Wang, J. Yoneda, T. Otsuka, S. Tarucha, and D. Loss, Single-Spin Manipulation in a Double Quantum Dot in the Field of a Micromagnet, Phys. Rev. B 90, 235311 (2014).
- [90] R. C. M. Li, J. A. Alusow, and R. C. Williamson, Surface-Wave Resonators using Grooved Reflectors, Proc. of 29th Annual Frequency Control Symp., 167-176 (1975).
- [91] O. E. Dial, M. D. Shulman, S. P. Harvey, H. Bluhm, V. Umansky, and A. Yacoby, *Charge Noise Spectroscopy Us*ing Coherent Exchange Oscillations in a Singlet-Triplet Qubit, Phys. Rev. Lett. **110**, 146804 (2013).
- [92] E. M. Kessler, Generalized Schrieffer-Wolff Formalism for Dissipative Systems, Phys. Rev. A 86, 012126 (2012).
- [93] E. M. Purcell, Spontaneous Emission Probabilities at Radio Frequencies, Phys. Rev. 69, 681 (1946).
- [94] K. M. Birnbaum, A. Boca, R. Miller, A. D. Boozer, T. E. Northup, and H. J. Kimble, *Photon Blockade in an Opti*cal Cavity with one Trapped Atom, Nature 436, 87(2005).
- [95] H. Tanji-Suzuki, W. Chen, R. Landig, J. Simon, and V. Vuletic, *Vacuum-Induced Transparency*, Science 333, 1266 (2011).
- [96] S. D. Bennett, S. Kolkowitz, Q. P. Unterreithmeier, P. Rabl, A. C. Bleszynski Jayich, J. G. E. Harris, and M. D. Lukin, *Measuring Mechanical Motion with a Single Spin*, New Journal of Physics **14**, 125004 (2012).
- [97] S. D. Bennett, N. Y. Yao, J. Otterbach, P. Zoller, P. Rabl, and M. D. Lukin, *Phonon-Induced Spin-Spin Inter*actions in Diamond Nanostructures: Application to Spin Squeezing, Phys. Rev. Lett. **110**, 156402 (2013).
- [98] V. Srinivasa and J. M. Taylor, Capacitively Coupled Singlet-Triplet Qubits in the Double Charge Resonant Regime, arXiv:1408.4740 (unpublished).